Review

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Lead-free metal-halide double perovskites: from optoelectronic properties to applications

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Abstract: Lead (Pb) halide perovskites have witnessed highly promising achievements for high-efficiency solar cells, light-emitting diodes (LEDs), and photo/radiation detectors due to their exceptional optoelectronic properties. However, compound stability and Pb toxicity are still two main obstacles towards the commercialization of halide perovskite-based devices. Therefore, it is of substantial interest to search for non-toxic candidates with comparable photophysical characteristics. Metal-halide double perovskites (MHDPs), $A_2BB'X_6$, are recently booming as promising alternatives for Pb-based halide-perovskites for their non-toxicity and significantly enhanced chemical and thermodynamic stability. Moreover, this family exhibits rich combinatorial chemistry with tuneable optoelectronic properties and thus a great potential for a broad range of

optoelectronic/electronic applications. Herein, we present a comprehensive review of the MHDPs synthesized so far, and classified by their optical and electronic properties. We systematically generalize their electronic structure by both theoretical and experimental efforts to prospect the relevant optoelectronic properties required by different applications. The progress of the materials in various applications is explicated in view of the material structure-function relationship. Finally, a perspective outlook to improve the physical and optoelectronic properties of the materials is proposed aiming at fostering their future development and applications.

Keywords: lead-free; metal-halide double perovskites; optoelectronic properties; photovoltaics; stability.

1 Introduction

Organic–inorganic halide perovskite solar cells have witnessed remarkable progress in the past few years with a rapid surge in the power conversion efficiency (PCE) from 3.8% in 2009 to 25.2% in 2019 [1–5]. Pb-based halide perovskites with a generic formula of ABX_3 exhibit great potential to pilot the next generation of photovoltaic technologies by approaching the record PCE for the high-efficiency silicon solar cells. This potential is attributed to some striking features of this class of materials, including narrow *direct* bandgap, long carrier diffusion length, high absorption coefficient, small and balanced electron and hole effective masses, small exciton binding energy and high carrier mobility [6–10]. Besides photovoltaics, organic-inorganic halide perovskites have extended their application into other fields, such as light-emitting diodes (LEDs) [11–14], X-ray detectors [15], photodetectors [16, 17], lasers [18] and batteries [19]. Despite this extraordinary potential and rocketing PCE improvement, these emerging technologies still face some barriers regarding insufficient stability against the operational conditions (heat, illumination and moisture) and toxic Pb inclusion in the light-absorbing layer [20].

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To improve the stability, some strategies have been adopted by regulating the crystal structure of the materials to enhance phase stability [3], defect passivation to suppress penetrating paths from the environment [21, 22], finding stable inorganic transporting layers [23], modulating dimensionality (D) of the halide perovskite absorbing layer from three-dimension (3D) to two-dimension (2D) [24, 25], and developing sophisticated encapsulation methods [26, 27]. On the other hand, toxicity is another challenge to be overcome, because Pb causes serious health concerns as a carcinogen [28]. Accordingly, significant efforts have been devoted to designing other Pb-free stable halide perovskites for different optoelectronic applications [29–31]. This demand has agitated substantial research efforts to explore potential elements of heavy *s*- and *p*-blocks (e.g. Sn, Ge, Bi and Sb) to fill the “B” position in the ABX_3 structure [32–38]. Sn and Ge were considered to be suitable substitutions of Pb. However, high-energy-lying 5s orbitals of these elements cause a high tendency of cation oxidation into Sn^{4+} and Ge^{4+} states [30, 31]. Bi^{3+} and Sb^{3+} with the same isoelectronic structure as Pb^{2+} have been inserted into the lattice, which lead to low-dimensional structures (0D, 1D, 2D) with the basic formula of $A_3B_2X_9$ [37–41]. In this category, face-sharing bioctahedral $[Bi_2I_9]^{3-}$ clusters are isolated by monovalent cations in the “A” position. This crystal structure leads to less impressive optical and electronic characteristics [22, 42], because the low dimensionality of Bi-based halide perovskite derivatives restricts efficient charge transport in the active layer, resulting in carrier localization in the isolated $[Bi_2I_9]^{3-}$ clusters [43–46]. Therefore, it is highly desirable to find metal-halide perovskites that can approximate the properties of the extensively studied $MAPbX_3$ ($MA = CH_3NH_3$) perovskites by using a non-toxic metal cation. Given the simple combinatory of ions charge in a perovskite structure of $A^+B^{2+}X_3$, a limited number of nontoxic and stable elements with the electron configuration of $d^{10}s^2$ or $d^{10}s^0$ can be contemplated for the “B” position. This situation can be overcome if we extend the exploration from ternary $A^+B^{2+}X_3$ perovskites to quaternary compositions.

$A_2BB'X_6$ double perovskites have been proposed as promising and stable substitutions for Pb-based halide perovskites, in which a vast number of 1^+ and 3^+ metal cations with appropriate electron configurations (e.g. Bi^{3+} , Sb^{3+} , In^{3+} , Cu^+ and Ag^+) can be accommodated in their lattice [47–50]. In fact, their oxide counterparts ($A_2BB'O_6$) have been intensively investigated previously with abundant material properties including ferromagnetic, ferroelectric, colossal magnetoresistance and multiferroic characteristics, and their application as scintillators in radiation detectors was also reported [51–53]. Additionally, there are some

reports on the exploration of double perovskites to tune the bandgap of oxide perovskites [54, 55]. Recently, $Cs_2AgBiBr_6$ has been proposed as a promising all-inorganic alternative for Pb-based perovskites, due to its remarkable stability [56], long carrier recombination lifetimes [48] and low carrier effective masses [50]. Early work has demonstrated a promising photovoltaic performance by incorporation of $Cs_2AgBiBr_6$ for solar cell application [57–62]. Although the maximum PCE reported so far for MHDPs is still far inferior to that of Pb halide perovskites [57–61], they have exhibited unique properties that extend their potential to other applications, such as sensors [63], photodetectors [64], radiation detectors [65, 66] and photocatalysis [67, 68] with encouraging initial results. However, concerning commercialization of these technologies using Pb halide perovskites is still on the way. In recent years, a few reviews have been published mainly focusing on the synthesis and crystal structure of MHDPs [69–72]. Relatively, an important aspect, the optoelectronic properties and the applications of these materials have rarely reviewed. Inspired by the extensive attention to these materials, we systematically review the electronic structures and photophysical properties of MHDPs in the electronic structure viewpoint of their bandgaps in this work. Following these sections, we discuss layer-structured MHDPs. Then we provide a perspective on the applications of materials through recognizing the required optoelectronic properties. Understanding the band structure of the materials is of paramount importance due to its intensive influence on the ultimate electronic structure, structural anti-site disorder, magnetic and electric properties [73, 74]. Therefore, identifying these aspects is essential to design new compounds with desired properties.

2 Indirect bandgap MHDPs

In addition to their intrinsically high stability, some optoelectronic properties of MHDPs such as carrier mobility and band structure extensively determine their potential applications with achievable performance. In Pb-based halide perovskites ($APbX_3$ where “A” = MA^+ , $FA^+ = CH(NH_2)_2^+$ or Cs^+ ; “X” = I^- , Br^- or Cl^-) the valence band and conduction band are principally contributed by X-5p and Pb-6p orbitals that stimulate the *direct* bandgap nature of these materials. Besides, the band structures can be moderately modified since the size of “A”-cation affects the halide frame tolerance against distortion/tilting [75]. A typical crystal structure of double perovskites with the afore-mentioned formula of $A_2BB'X_6$ contains corner-sharing octahedral where “A” cation is in the middle of the cuboctahedral cavity, similar to their $MAPbX_3$ analogues [49]. The difference is that in

double perovskites the centres of the octahedra are alternatively occupied by either monovalent (B^+) or trivalent (B^{3+}) metal cations leading to a rock-salt configuration. To date, high-throughput computational investigations have explored the electronic properties of these compounds for optoelectronic application, while there are just a few reports on successful synthesis of MHDPs [50, 76].

2.1 A_2BBiX_6 ($A = MA^+, Cs^+$; $B = Ag^+, K^+$; $X = Cl^-, Br^-$ and I^-)

2.1.1 Cs_2AgBiX_6 ($X = I^-, Br^-$ and Cl^-)

In Pb-based halide perovskites, the bandgap transition is associated with a ligand-to-metal charge transfer between the predominant halide p -orbitals at the valence band maximum (VBM) and Pb p -orbitals at the conduction band minimum (CBM) [77]. Typical electronic configuration of Pb^{2+} ($6s^26p^0$) allows the contribution of filled $6s$ orbitals alongside the halide $5p$ orbitals into the valence band, while the conduction band is formed by the unoccupied Pb- $6p$ orbitals. This orbital contribution leads to a *direct* bandgap for this class of materials. Diverse theoretical and experimental studies have identified this specific composition of VBM and CBM as the main origin of some particular characteristics of Pb-based perovskites such as long carrier lifetime and shallow defect states [78–80]. Besides, the rich p -orbital-based density of states in the vicinity of the band edges induces strong absorption of the material [80]. Given this, just three main groups of elements of Tl^+ , Pb^{2+} and Bi^{3+} show stable cations with an electronic configuration of $6s^26p^0$, among which only Bi^{3+} is rated as a low toxic element. In fact, for decades, Bi has been applied as the nontoxic substitution for toxic Pb in different fields from organic synthesis to supply arms and ammunition [81]. Coordination anthologies of Bi are also frequently used in over-the-counter medications (e.g. Pepto-Bismol) [82]. In 2016, different research groups reported the first investigations of optical and structural properties of MHDPs by synthesizing Cs_2AgBiX_6 ($X = Br, Cl$) powder [47–50]. The compounds crystallized in a 3D elpasolite K_2NaAlF_6 architecture via either conventional solid-state reaction or solution-processing methods. The UV–Vis diffuse reflectance spectra of the samples showed striking similarities to those Pb-based analogues (Figure 1a and b). However, it was observed that the onset of the absorption spectrum is not as sharp as those for Pb-based perovskites, which was attributed to the *indirect* nature of the materials' bandgap [49]. By transferring the reflectance data to the pseudo-absorption data using Kubelka-Munk equation

(Equation 1), the absorbance is defined as a function of reflectance [49].

$$F(R) = \alpha = (1 - R)^2 / 2R \quad (1)$$

where α is the optical absorption coefficient and R is the reflectance. Then applying the Tauc method on the transformed data, utilizing the equation of $[F(R)h\nu]^{1/\gamma}$ versus $h\nu$ with $\gamma = 1/2$ for *indirect* transitions and $\gamma = 2$ for *direct* transitions (Figure 1c and d), the bandgap of the materials was determined. Adopting this approach *indirect* bandgaps of 2.77 and 2.19 eV were calculated for $Cs_2AgBiCl_6$ and $Cs_2AgBiBr_6$, respectively. With the same strategy, Slavney et al. [48] measured the bandgap of the $Cs_2AgBiBr_6$ powder (Figure 1e). Regarding the *indirect* nature of the bandgap, the linear region of the plot was assumed as the expected photon-assisted transitions, in which a phonon is absorbed in 1.83 eV and emitted at 2.07 eV (Figure 1e, inset) [48]. Therefore, *indirect* bandgap energy of 1.95 eV was estimated for the $Cs_2AgBiBr_6$ compound with assisting phonon energy of 0.12 eV.

At room temperature, $Cs_2AgBiBr_6$ displayed a weak photoluminescence (PL) peak at 1.87 eV (Figure 1f) with a blue-shift to 1.98 eV at a low temperature of 23 K (Figure 1f, inset) [48]. Time-resolved PL (TRPL) measurement could determine the dynamics of photogenerated carriers (Figure 1g) [48]. From TRPL curves, an initial fast drop accompanied by a slower decay was observed for $Cs_2AgBiBr_6$. The PL decay trace could be well fitted by three-exponential functions, which suggested its three dynamic processes: T_1 as the short-lifetime process ($T_1 < 1$ ns), T_2 as the intermediate-lifetime ($T_2 = 50$ –150 ns) and T_3 as the long-lived part ($T_3 \sim 660$ ns). Full fitting parameters for single-crystal and powder samples are listed in Table 1 that shows the short and intermediate lifetimes of the powder are much shorter than those of single-crystals. Owing to much more surface states in powder, the short- and intermediate-lifetime components should be related to the surface-state emission. On the other hand, no significant difference of long PL decay time between the single-crystals and powders could be recognized (ca. 660 ns), which indicated this component may originate from the fundamental recombination of $Cs_2AgBiBr_6$.

Further investigation was also conducted to determine the materials' electronic structure by calculating their band structure (Figure 1i–l) [48, 49]. Regardless of many similarities between the band structure of Cs_2AgBiX_6 ($X = Br$ and Cl) double perovskites and Pb-halide perovskites, there is a significant difference that confirms the *indirect* bandgap of Cs_2AgBiX_6 ($X = Br$ and Cl) double perovskites. This conclusion comes from the fact that in double perovskite compounds, the VBM shifts from R -point of the Brillouin zone in

Figure 1: Diffuse reflectance spectra for (a) $\text{Cs}_2\text{AgBiBr}_6$ (blue) and $\text{CH}_3\text{NH}_3\text{PbBr}_3$ (red) and (b) $\text{Cs}_2\text{AgBiCl}_6$ (blue) and $\text{CH}_3\text{NH}_3\text{PbCl}_3$ (red) [49]. Copyright 2016, American Chemical Society. Kubelka–Munk plots for (c) $\text{Cs}_2\text{AgBiBr}_6$ (blue) and $\text{CH}_3\text{NH}_3\text{PbBr}_3$ (red) and (d) $\text{Cs}_2\text{AgBiCl}_6$ (blue) and $\text{CH}_3\text{NH}_3\text{PbCl}_3$ (red) [49]. Copyright 2016, American Chemical Society. (e) Absorbance spectrum of $\text{Cs}_2\text{AgBiBr}_6$ powder. Inset: Tauc plot of $\text{Cs}_2\text{AgBiBr}_6$ [48]. Copyright 2016, American Chemical Society. (f) Photoluminescence (PL) spectrum of $\text{Cs}_2\text{AgBiBr}_6$ powder. Inset: low-temperature PL spectrum [48]. Copyright 2016, American Chemical Society. (g) Time-resolved room-temperature PL (TRPL) of $\text{Cs}_2\text{AgBiBr}_6$ powder and single-crystals [48]. Copyright 2016, American Chemical Society. (h) Calculated electronic bandgaps for all compounds in the halide double perovskite family with ‘ B^{3+} ’ sites of Bi^{3+} and Sb^{3+} [50]. Copyright 2016, American Chemical Society. Band structure diagrams for (i) $\text{Cs}_2\text{AgBiBr}_6$, (j) $\text{Cs}_2\text{AgBiCl}_6$, (k) cubic CsPbBr_3 and (l) cubic CsPbCl_3 [49]. Copyright 2016, American Chemical Society. Atomic partial density of states (PDOS) plots for (m) $\text{Cs}_2\text{AgBiBr}_6$ and (n) $\text{Cs}_2\text{AgBiCl}_6$ [49]. Copyright 2016, American Chemical Society. (o) Comparison of the molecular orbital diagrams of $\text{Cs}_2\text{AgBiCl}_6$ (left) and $\text{Cs}_2\text{AgBiBr}_6$ (right) [47]. Copyright 2016, American Chemical Society. (p) Energy band levels of $\text{Cs}_2\text{AgBiBr}_6$ relative to other hole-/electron-transporting layers [62]. 2020 Wiley-VCH GmbH. (q) Kubelka–Munk plot for $\text{MA}_2\text{AgBiI}_6$ [86]. Copyright 2015, Royal Society of Chemistry. (r) The optimized structure of $\text{MA}_2\text{AgBiI}_6$ [86]. (s) Band energy diagram of $\text{MA}_2\text{AgBiI}_6$ [86]. Copyright 2015, Royal Society of Chemistry.

a primitive cubic cell to X -point, while the CBM locates at L -point of the Brillouin zone [49, 83]. From the curvature of the bands, an estimation of the compounds’ effective charge carrier masses was determined. This approach showed

the effective masses of electron and hole were $0.53m_e$ and $0.15m_e$, respectively, for $\text{Cs}_2\text{AgBiCl}_6$, while the corresponding magnitudes for $\text{Cs}_2\text{AgBiBr}_6$ were $0.37m_e$ and $0.14m_e$ [49]. This highlights smaller hole effective masses for

Table 1: Full fit of the TRPL data for $\text{Cs}_2\text{AgBiBr}_6$ single-crystal and powder samples [48].

Compound	T_1 (ns)	T_2 (ns)	T_3 (ns)
$\text{Cs}_2\text{AgBiBr}_6$ single-crystals	0.54	145	668
$\text{Cs}_2\text{AgBiBr}_6$ powders	0.204	54	657

double perovskite compounds than those of Pb-halide perovskites [50].

Partial density of state (PDOS) measurement showed a valence to conduction band transition in $\text{Cs}_2\text{AgBiX}_6$ ($X = \text{Br}$ and Cl) double perovskites from the filled $3p/4p$ orbitals of halogens to Bi- $6p$ and Ag- $5s$ states (Figure 1m and n). Relatively flat bands due to extensive presence of Ag- $4d$ orbitals in the valence band should be partially responsible for the *indirect* bandgap characteristic in these compounds [49]. Figure 1o illustrates the changes of electronic structure for different halogen atoms in which by moving from Cl to Br, a reduction in the valence bandwidth and a slight rise in the VBM are observed. This ignites the bandgap shrinkage for the case of Br halogen, because the energy difference between the Ag- $4d$ and Br- $4p$ levels is smaller than that of Ag- $4d$ and Cl- $3p$ states. Br- $4p$ orbitals with higher energy cause a shift towards higher energy levels. Similarly, Volonakis et al. performed density functional theory (DFT) calculations on a range of MHDPs whose “B⁺” and “B³⁺” sites are occupied by metal cations of Cu⁺, Ag⁺ and Au⁺ and pnictogen cations of Bi³⁺ and Sb³⁺, respectively [50]. They discussed that by moving down the halogens in the periodic table column, a reduction in the bandgap value of the investigated double perovskite structures appeared [50]. Additionally, the investigation of the monovalent and trivalent metal cations at “B⁺” and “B³⁺” sites showed that the bandgap magnitude was affected by the size of “B³⁺” cation, while no monotonic shift concerning the size of the “B⁺” noble-metal cation could be seen (Figure 1h). This behaviour was contributed to the energy of the pnictogen- p orbitals ($B^{3+} = \text{Bi}^{3+}, \text{Sb}^{3+}$), which decreased by increasing the atomic number in the periodic table column, hence lowering the energy of the CBM. The energy band alignments of the $\text{Cs}_2\text{AgBiBr}_6$ double perovskite thin-film indicated a valence band and conduction band levels of 6.39 and 4.00 eV, respectively, which are rather well-positioned relative to other frequently used hole- and electron-transporting layers in the solar cell application (Figure 1p) [62].

Although successful synthesis of $\text{Cs}_2\text{AgBiBr}_6$ through different approaches of solution processes and solid-state reaction, the iodide-based compound of $\text{Cs}_2\text{AgBiI}_6$ can be hardly form through these commonly used protocols. This

barrier has been assigned to the negative decomposition enthalpy of this composition ($-47 \text{ meV atom}^{-1}$) through the following reaction of $\text{Cs}_2\text{AgBiI}_6 \rightarrow 1/2\text{CsAg}_2\text{I}_3 + 1/2\text{Cs}_3\text{Bi}_2\text{I}_9$ [84]. Nevertheless, Creutz et al. [85] reported the synthesis of colloidal nanocrystals of $\text{Cs}_2\text{AgBiI}_6$ by post-synthetic modification of $\text{Cs}_2\text{AgBiBr}_6$ nanocrystals through a novel anion-exchange method. A strong absorption over the visible region with an indirect bandgap of 1.75 eV was obtained for the $\text{Cs}_2\text{AgBiI}_6$ product. Despite this achievement, the intrinsic thermodynamic instability of $\text{Cs}_2\text{AgBiI}_6$ is still a problem that causes the decomposition of the single-crystals after several days of storing in ambient conditions.

Combining theoretical and experimental studies, the synthesis of $\text{MA}_2\text{AgBiI}_6$ perovskite single-crystals also has been reported, however, with a larger bandgap of 1.96 eV than that predicted one by calculations (1.63 eV) (Figure 1q). Likewise, this compound showed indirect bandgap characteristics with an outstanding air stability of four-months storage in ambient condition and no trace of material decomposition, whereas the crystal structure was found to be in the orthorhombic crystal system (Figure 1r) [86]. The results show that $\text{MA}_2\text{AgBiI}_6$ is a suitable candidate for tandem solar cells. The band dispersion around the conduction band and valence band leads to an imbalanced electron effective mass and hole effective mass of $0.47 m_e$ and $0.70 m_e$ (m_e is the electron static mass) calculated for the material, which indicates better electron-transport efficiency than holes. However, the energy band diagram implies that electron transfer from the $\text{MA}_2\text{AgBiI}_6$ perovskite well-known electron-collecting layers should be problematic and in some cases inhibited (Figure 1s). This emphasizes more the importance of the band-alignment engineering of the constituent layers to fully realize the potential of the material for photovoltaics.

2.1.2 $\text{MA}_2\text{KBiCl}_6$

Due to different optical properties of hybrid perovskites plus their feasible implementation into devices of a specific function [87], Wei et al. [88] investigated the formation of hybrid MHDPs. It was found that $\text{MA}_2\text{KBiCl}_6$ crystallizes in rhombohedral $R\bar{3}m$ symmetry to form a 3D network of alternatingly corner-sharing $(\text{KCl}_6)^{5-}$ and $(\text{BiCl}_6)^{3-}$ octahedra (Figure 2a–c). In this structure, organic cation of MA^+ occupied the cavity between the octahedra (Figure 2c) with a distortion into the lattice due to the different ionic radii of $\text{K}^+(1.38 \text{ \AA})$ and $\text{Bi}^{3+}(1.03 \text{ \AA})$. UV–Vis spectrometry measured the optical bandgap of $\text{MA}_2\text{KBiCl}_6$ with *indirect* semiconductor characteristics (Figure 2d). From the corresponding Tauc plot, two

different values of 3.04 and 3.37 eV were extracted for the apparent bandgaps of $\text{MA}_2\text{KBiCl}_6$ (Figure 2e). DFT calculations helped to interpret the band structure of the material (Figure 2f–g) that predicted *indirect* and *direct* bandgaps of 3.02 and 3.15 eV, respectively. The VBM and CBM band edges were found at *L*- and *A*-points of the Brillouin zone that indicated the *indirect* characteristics of the bandgap of the material. PDOS measurements revealed VBM mainly composed of Bi-6s and Cl-3p antibonding states, while in CBM the main contribution came from the Bi-6p, Cl-3p antibonding states with a small portion for Cl-3s states (Figure 2h). Organic cation of MA^+ did not present in the states near VBM or CBM, previously seen in MAPbI_3 [89]. Additionally, due to low-lying energy states of K^+ , the K-3p states position at ~ 13 eV below the VBM, therefore, no trace of K^+ contribution in the material's VBM and CBM could be seen. This is totally different

from the case of $\text{Cs}_2\text{AgBiBr}_6$ where Ag^+ indicated a clear contribution in the states near the VBM of the material.

2.1.3 $\text{MA}_2\text{AgBiBr}_6$

Wei et al. expanded the efforts to search for hybrid MHPs by synthesizing a new environmentally friendly hybrid double perovskite of $\text{MA}_2\text{AgBiBr}_6$ [90]. Similar to its all-inorganic analogue ($\text{Cs}_2\text{AgBiBr}_6$), the presented material crystallized in $Fm\bar{3}m$ space group with alternating $(\text{BiBr}_6)^{3-}$ and $(\text{AgBr}_6)^{5-}$ octahedra to form a 3D architecture (Figure 2i). From the material's absorption spectrum, a cut-off wavelength of ~ 620 nm was extracted (Figure 2j). This generated an *indirect* bandgap of 2.02 eV (Figure 2k), which is smaller than those reported for MAPbBr_3 (2.2–2.3 eV) [91]. Although this bandgap is assumed to be narrow enough to

Figure 2: Crystal structure of $\text{MA}_2\text{KBiCl}_6$, along (a) the *c*-axis, (b) the *a*-axis and (c) tilted to show the MA location. (d) Absorption spectra and (e) the Tauc plot of $\text{MA}_2\text{KBiCl}_6$ [88]. Copyright 2015, Royal Society of Chemistry. (f) Calculated band structure of $\text{MA}_2\text{KBiCl}_6$ [88]. Copyright 2015, Royal Society of Chemistry. (g) Enlarged view of the band structure near the bandgap of $\text{MA}_2\text{KBiCl}_6$ [88]. Copyright 2015, Royal Society of Chemistry. (h) Calculated total and PDOS of $\text{MA}_2\text{KBiCl}_6$ [88]. Copyright 2015, Royal Society of Chemistry. (i) Crystal structure of $\text{MA}_2\text{AgBiBr}_6$ [90]. Copyright 2017, American Chemical Society. (j) Absorption spectrum and (k) Tauc plot of $\text{MA}_2\text{AgBiBr}_6$ [90]. Copyright 2017, American Chemical Society. (l) Calculated band structure and (m) PDOS of $\text{MA}_2\text{AgBiBr}_6$ [90]. Copyright 2017, American Chemical Society.

observe semiconducting behaviour, a small ionic conductivity of $4.8 \times 10^8 \Omega \text{ cm}$ could be measured for the proposed material. This suggested the electronic conductivity of $\text{MA}_2\text{AgBiBr}_6$ should be probably far smaller than that of MAPbBr_3 due to a limited number of carriers with low mobility. DFT and PDOS calculations showed an *indirect* transition from *X*-point to the *L*-point of the Brillouin zone (Figure 2l). PDOS confirmed the main contributions of VBM originated from Bi-6s, Ag-4d and Br-4p states, whereas CBM mostly contained Ag-5s, Bi-6p and Br-4p states, similar to the case of $\text{Cs}_2\text{AgBiBr}_6$. No significant contribution of MA^+ cations in the band edges could be found, while the contribution of the Ag-4d states in the materials VBM led to the *indirect* transition at the band edges for $\text{MA}_2\text{AgBiBr}_6$ (Figure 2m). Calculating the carrier effective masses of both compounds presented very similar values to $\text{Cs}_2\text{AgBiBr}_6$ that was due to their rather resembling band dispersion (Table 2).

2.2 Cs_2BSbX_6 ($\text{B} = \text{Ag}^+, \text{Cu}^+$; $\text{X} = \text{Cl}^-$ and Br^-)

2.2.1 $\text{Cs}_2\text{AgSbCl}_6$

To design a general strategy to tune the convergence of *indirect* and *direct* bandgap by chemical adjustment of the *s*-state and *p*-state characteristics of MHDPs, Tran et al. [92] successfully synthesized two types of halide double perovskites: $\text{Cs}_2\text{AgSbCl}_6$, with an *indirect* bandgap, and $\text{Cs}_2\text{AgInCl}_6$, with a *direct* bandgap. The viability of their strategy will be discussed in the following sections. Here, the optoelectronic properties of newly designed $\text{Cs}_2\text{AgSbCl}_6$ are particularly propounded. $\text{Cs}_2\text{AgSbCl}_6$ is isostructural of $\text{Cs}_2\text{AgBiBr}_6$ and crystallizes in $Fm\bar{3}m$ space group. The framework of the material likewise contains corner-sharing intermittent octahedra of $[\text{SbCl}_6]^{3-}$ and $[\text{AgCl}_6]^{5-}$ stacked to each other in a 3D skeleton, with Cs^+ cations located in the cavity in between the octahedra. The UV–Vis diffuse reflectance spectra measurement indicated a shallow absorption edge at around 2.54 eV accompanied by a sharp increase in the absorption at 2.79 eV, which revealed the specific characteristics of an *indirect* bandgap semiconductor (Figure 3a). From the linear region of the material's Tauc plot, the phonon-assisted processes can be seen that indicated a phonon absorption and emission by transitions at 2.54 and 2.79 eV. To argue the electronic structure of the material, DFT calculations confirmed that $\text{Cs}_2\text{AgSbCl}_6$ owned an *indirect* bandgap with the VBM and CBM situated at the *W*-point and *X*-point of the Brillouin zone, severally (Figure 3b). PDOS measurements were exploited to create the band diagram for the proposed material (Figure 3c). The results showed that the material's VBM is predominantly

constructed from antibonding Ag-4d/Cl-3p states, where a stronger Cl-3p characteristic is conducted. On the other hand, Ag-s states were raised to the CB to have an interaction with the Sb-p stats. Additionally, it was seen that the isolated conduction band mostly originated from the spin-orbit-effect, due to a split between the contributed Sb-5p_{1/2} and Sb-5p_{3/2} states. Given this information, it is derived that antibonding Sb-p/Cl-p states were the dominant orbitals at the CB of the $\text{Cs}_2\text{AgBiCl}_6$.

2.2.2 $\text{Cs}_2\text{AgSbBr}_6$

All the above-mentioned double perovskites possess wide-bandgap ranging from 1.9 to 3.37 eV, which arises some concerns on their capability as an efficient light harvester. One way to reduce the bandgap is replacing Br^- with I^- , in which owing to the interaction between the I-5p orbitals and metal cations, a drop in the CBM, as well as a rise in the VBM, and consequently a reduction in the material's bandgap occurs [93]. However, the synthesis of iodide-based double perovskites has been proven to be impossible experimentally, such that even a small amount of iodine deployment into the structure results in the material decomposition to lower-dimensional $\text{A}_3\text{Bi}_2\text{I}_9$ phases. Another approach is to adopt a B^{3+} cation with an electron configuration of 5s–5p instead of the commonly used one with a 6s–6p electronic state (e.g. Bi^{3+}). Regarding these, Wei et al. [94] focussed on the substitution of Bi^{3+} in the $\text{Cs}_2\text{AgBiBr}_6$ structure with Sb^{3+} to provide a new low bandgap MHDP. In common with most members of the double perovskite family, $\text{Cs}_2\text{AgSbBr}_6$ also crystallized in the cubic $Fm\bar{3}m$ space group forming typical rock-salt architecture of double perovskites. One interesting fact related to this newly designed material was that upon heating at 480 K for 5 min in an inert atmosphere, a colour change from black to brown was observed that was found to be an irreversible transition. To uncover the origin of this phenomenon, X-ray photoelectron spectroscopy (XPS) measurements on both black and brown crystals showed the existence of Sb^{5+} in black crystals by detecting Sb-3d_{5/2} corresponding peak at 540.5 eV. On the contrary, no trace of this peak could be found in the brown crystal. Hence, the reason for this colour change was hypothesized to be rooted in the charge transport between Sb^{3+} and Sb^{5+} in the black phase [94].

Similar to its Cl-based analogue, the Tauc plot of $\text{Cs}_2\text{AgSbBr}_6$ black crystals also showed a shallow absorption edge at 1.64 eV with a sharp increase at 2.49 eV (Figure 3d). Given these, an *indirect* bandgap of 1.64 was estimated for the material, which was considerably less than those reported for $\text{Cs}_2\text{AgBiBr}_6$ (~1.95–2.19 eV) and also

Table 2: Summary of the optoelectronic parameters of the MHDPS.

Material	E_g (eV)	E_g Nature	Dimensionality	Crystal system	e^- effective-mass (m_e)	h^+ effective-mass (m_e)	VBM orbitals	CBM orbitals	Ref
$\text{Cs}_2\text{AgBiBr}_6$	2.19	Indirect	3D	Cubic $Fm\bar{3}m$	0.37	00.14	Ag-4d/Br-4p	Ag-5s/Bi-6p	[35, 47–49]
$\text{Cs}_2\text{AgBiCl}_6$	2.77	Indirect	3D	Cubic $Fm\bar{3}m$	0.53	00.15	Ag-4d/Cl-3p	Ag-5s/Bi-6p	[47, 49, 50]
$\text{MA}_2\text{AgBiI}_6$	1.96	Indirect	3D	Orthorhombic	0.47	00.70	Ag-4d/Bi-6p/I-5p	Bi6p/I-5p	[86]
$\text{MA}_2\text{KBiCl}_6$	3.37	Indirect	3D	Rhombohedral $R\bar{3}m$	–	–	Bi-6s/Cl-3p	Bi-6p/Cl-3p/Cl-3s	[88]
$\text{MA}_2\text{AgBiBr}_6$	2.02	Indirect	3D	Cubic $Fm\bar{3}m$	0.21	00.24	Ag-4d/Bi-6s/Br-4p	Ag-5s/Bi-6p/Br-4p	[90]
$\text{Cs}_2\text{AgSbCl}_6$	2.54	Indirect	3D	Cubic $Fm\bar{3}m$	–	–	Ag-4d/Cl-3p	Sb-5p/Cl-3p	[92]
$\text{Cs}_2\text{AgSbBr}_6$	1.64	Indirect	3D	Cubic $Fm\bar{3}m$	0.27	00.23	Ag-4d/Sb-5s/Br-4p	Sb-5p/Br-4p	[94]
$\text{Cs}_2\text{CuSbCl}_6$	1.66	Indirect	3D	Cubic $Fm\bar{3}m$	–	–	Cu-3d/Sb-5s/Cl-3p	Sb-5p/Cl-3p/Cl-3s	[97]
$\text{Cs}_2\text{AgInCl}_6$	3.3	Direct	3D	Cubic $Fm\bar{3}m$	0.29	0.28	Ag-4d/In-4d/Cl-3p	Ag-5s/In-5s/Cl-3p	[100]
$\text{Cs}_2\text{AgTlCl}_6$	1.96	Direct	3D	Cubic $Fm\bar{3}m$	0.23	00.26	Ag-4d	Ag-5s/Tl-6s	[110]
$\text{Cs}_2\text{AgTlBr}_6$	0.95	Direct	3D	Cubic $Fm\bar{3}m$	0.27	00.33	Ag-4d	Ag-5s/Tl-6s	[110]
$\text{MA}_2\text{TlBiBr}_6$	2.16	Direct	3D	Cubic $Fm\bar{3}m$	–	–	Tl-6s/Bi-6s/I-5p	Tl-6s/Bi-6p/I-5p	[93]
MA_2KdCl_6	4.91	Direct	3D	Rhombohedral ($R\bar{3}m$)	–	–	Cl-3p	Gd-5d/Cl-3p	[122]
MA_2KYCl_6	5.04	Direct	3D	Rhombohedral ($R\bar{3}m$)	–	–	Cl-3p	Y-4d/Cl-3p	[122]
$\text{Cs}_2\text{Ag}(\text{Bi}_{0.25}\text{In}_{0.75})\text{Br}_6$	2.27	Indirect	3D	Cubic $Fm\bar{3}m$	–	–	Ag-4d/Bi-6s/Br-4p	In-5s/Bi-6p	[130]
$\text{Cs}_2\text{Ag}(\text{Bi}_{0.63}\text{Sb}_{0.37})\text{Br}_6$	1.86	Indirect	3D	Cubic $Fm\bar{3}m$	–	–	Ag-4d/Sb-5s/Br-4p	Bi-6p/Sb-5p	[130]
$\text{Cs}_2(\text{Ag}_{0.97}\text{Bi}_{0.97})\text{Tl}_{0.06}\text{Br}_6$	~1.5	Indirect	3D	Cubic $Fm\bar{3}m$	0.63	0.58	Ag-4d/Bi-6s	Ag-4d/Tl ³⁺ -6s	[132]
$\text{Cs}_2\text{Ag}_{0.99}\text{Sb}_{0.99}\text{Cu}_{0.2}\text{Cl}_6$	1.02	Indirect	3D	Cubic $Fm\bar{3}m$	–	–	Ag-4d/Cu-3d/Cl-3p	Sb-5p/Cl-3p	[133]
$\text{Cs}_2\text{AgSb}_{0.5}\text{In}_{0.5}\text{Cl}_6$	2.81	Direct	3D	Cubic $Fm\bar{3}m$	–	–	Ag-4d/Sb-5s/Cl-3p	In-5s/Sb-5p/Cl-3p	[92]
$\text{Cs}_2\text{AgFeCl}_6$	1.55	Direct	3D	Cubic $Fm\bar{3}m$	–	–	–	–	[142]
$\text{Rb}_4\text{Ag}_2\text{BiBr}_9$	2.82	Indirect	2D	Orthorhombic $Pnmm$	–	–	Ag-4d/Br-4p	Bi-6p/Br-4p	[149]
$\text{Cs}_4\text{CuSb}_2\text{Cl}_{12}$	1.00	Direct	2D	Monoclinic $C2/m$	0.32	0.16	Cu-3d/Cl-3p	Sb-5p/Cl-3p	[152]
$(\text{BA})_2\text{CsAgBiBr}_7$	2.96	Indirect	2D	–	–	–	Ag-4d/Bi-6s/Br-4p/	Ag-5s/Bi-6p/Br-4p	[119]
$(\text{BA})_4\text{AgBiBr}_8$	3.01	Direct	2D	–	–	–	Ag-4d/Br-4p	Bi-6p/Br-4p	[119]
$\text{Cs}_4\text{GeSb}_2\text{I}_{12}$	1.76	Direct	2D	Monoclinic, ($C2/m$)	0.53	2.81	Sn-5s	Ge-4p/Sb-5p	[166]
$\text{Cs}_4\text{SnSb}_2\text{I}_{12}$	1.66	Direct	2D	Monoclinic, ($C2/m$)	0.59	3.19	Ge-5s	Sn-5p/Sb-5p	[166]

Figure 3: (a) Tauc plots for $\text{Cs}_2\text{AgSbCl}_6$ double perovskite [92]. Copyright 2015, Royal Society of Chemistry. (b) Band structure of $\text{Cs}_2\text{AgSbCl}_6$ double perovskite. (c) PDOS of $\text{Cs}_2\text{AgSbCl}_6$ double perovskite [92]. Copyright 2015, Royal Society of Chemistry. (d) Tauc plot of a black sample of $\text{Cs}_2\text{AgSbBr}_6$ powder [94]. Copyright 2015, Royal Society of Chemistry. The inset shows the indirect bandgap absorption edge. (e) Calculated electronic band structures of $\text{Cs}_2\text{AgSbBr}_6$ and $\text{Cs}_2\text{AgBiBr}_6$ double perovskites [94]. Copyright 2015, Royal Society of Chemistry. (f) PDOS of $\text{Cs}_2\text{AgSbBr}_6$ and $\text{Cs}_2\text{AgBiBr}_6$ double perovskites [94]. Copyright 2015, Royal Society of Chemistry.

$\text{Cs}_2\text{AgSbCl}_6$ (2.54 eV) [47, 48, 92]. To understand the band structure of $\text{Cs}_2\text{AgSbBr}_6$, the calculations were performed on both $\text{Cs}_2\text{AgBiBr}_6$ and $\text{Cs}_2\text{AgSbBr}_6$ powders. From Figure 3e, a significant similarity between the band structures of the two compounds can be seen. The VBM of $\text{Cs}_2\text{AgSbBr}_6$ locates at the X-point with a majority of Ag-4d/Br-4p antibonding states and a minima portion of Sb-5s orbitals (Figure 3f). However, the presiding states at the CBM of the materials are dependent on the Sb-5p/Br-4p antibonding states. Sb-5p interaction yields a wide

dispersion in the conduction band and lowering the band edge at the L-point, causing a much narrower calculated bandgap of 1.46 eV compared with that of $\text{Cs}_2\text{AgBiBr}_6$ (1.84 eV). Calculating electron and hole effective masses of both compounds from their band structure demonstrated relatively lower values for $\text{Cs}_2\text{AgSbBr}_6$ (Table 2). This is in consistent with the general trend that in large bandgap materials the valence band and conduction band are normally less dispersed, steering a decrease in the charge carrier mobility [95].

2.2.3 $\text{Cs}_2\text{CuSbCl}_6$

Theoretical calculations predicted that Cu^+ -based MHDPs may lead to a suitable bandgap for photovoltaic applications. Nevertheless, the synthesis of their bulk crystal is not yet feasible due to the problems of high formation energy and kinetic instability of the compounds. The reason of this has been shown to originate from the tendency of Cu^+ with electronic configuration of the $[\text{Ar}] 3d^{10} 4s^1$ to form a four-fold coordination $[\text{CuX}_4]$ tetrahedral in a non-perovskite structure rather than the sixfold $[\text{CuX}_6]$ octahedral for double-perovskites configuration [96]. Zhou et al. [97] speculated that hot-injection method may overcome this obstacle and facilitate the crystallization of the material at the nanoscale. The reason for this hypothesis was the intense and rapid precursors' reaction through this approach. Therefore, they reported the successful colloidal synthesis of all-inorganic Cu^+ -based MHDP of $\text{Cs}_2\text{CuSbCl}_6$ nanocrystals. The material showed a highly symmetric face-centred cubic structure in a $Fm\bar{3}m$ crystal system (Figure 4a). X-ray diffraction (XRD) characterization confirmed high crystallinity of nanocrystals with a single pure phase (Figure 4b). The nanocrystals showed the ability to absorb light from the entire visible region with a promising narrow optical bandgap of 1.66 eV (Figure 4c). The relatively narrow bandgap of $\text{Cs}_2\text{CuSbCl}_6$ nanocrystals highlighted its great potential as light-absorbing material. Using nanosecond transient absorption (TA) spectroscopy, a fast decay component of $\tau_1 = 1.5\text{--}2$ ps related to the fast cooling of dark trapped states, an intermediate lifetime of $\tau_2 = 50\text{--}85$ ps attributed to the surface defect trap states, and long lifetime of $\tau_3 = 148$ ns assigned to the dark trapped state were calculated for the material (Figure 4d). These results emphasized the importance of further understanding the non-radiative process of MHDPs and revealed the reason for the poor PL properties normally possessed by Sb-based materials. To explain the electronic properties of $\text{Cs}_2\text{CuSbCl}_6$ nanocrystals, DFT calculations confirmed the indirect electronic bandgap of the material (Figure 4e). Because the VBM is positioned at the X-point, while CBM is located at the L-point. It was seen that in VBM the contribution of the $\text{Cu-}3d/\text{Sb-}5s/\text{Cl-}3p$ orbitals were dominant, whereas the CBM was significantly contributed by $\text{Sb-}5p/\text{Cl-}3p/\text{Cl-}3s$ states (Figure 4f).

3 Direct bandgap MHDPs

While the proposed MHDPs exhibit acceptable bandgap values in the visible range, one immediate challenge for these materials is their *indirect* bandgap that suppresses

their potential for thin-film photovoltaic application. Generally, *indirect* bandgaps show weak oscillator abilities for either light absorption or radiative recombination, accordingly much thicker absorbing-layer is necessary for *indirect* bandgap semiconductors. On the other hand, if charge carrier mobility of the operating layer is not high enough, an optimum thickness applies. To circumvent this barrier, several works have been reported to develop new Pb-free MHDPs with a *direct* bandgap that will be discussed in this section.

3.1 $\text{Cs}_2\text{AgInCl}_6$

Inspired by the previous reports indicating In^{3+} deployment in an elpasolite structure of $\text{Cs}_2\text{NaB}^{3+}\text{X}_6$ ($\text{X} = \text{Cl}, \text{Br}, \text{I}$) [98, 99], Volonakis et al. [100] assessed the formation of hypothetical compounds of $\text{Cs}_2\text{AgInX}_6$ ($\text{X} = \text{Cl}, \text{Br}, \text{I}$) with the predicted *direct* bandgap. As a result, they succeeded in synthesizing $\text{Cs}_2\text{AgInCl}_6$ with typical rock-salt ordering found in many double perovskites within a $Fm\bar{3}m$ symmetry. Precise evaluation of the absorbance spectrum of the material revealed an absorption onset at 380 nm corresponding to the bandgap of 3.3 eV, with a further absorption feature located at 585 nm (bandgap of 2.1 eV) (Figure 4g and h). The interesting point is that a material with a bandgap of 2.1 eV should be in orange, while the synthesized $\text{Cs}_2\text{AgInCl}_6$ powder was in white. Examining the material's reaction under photoexcitation revealed a colour change from white to orange under UV illumination. This phenomenon might be correlated with some structural changes or photoinduced electronic variations in the material [101, 102]. One similar example is that the AgCl is a photosensitive compound with a shift in its oxidation state under light-illumination. This reversible photochromic behaviour can also be due to the extensive sensitivity of the $\text{Cs}_2\text{AgInCl}_6$ electronic structure to the marginal difference between the In-Cl and Ag-Cl bond lengths. Thus, it was presumed that the absorption onset at 2.1 eV might arise from the photoinduced defect states upon light-illumination, while the actual onset was at 3.3 eV. Employing DFT calculations, a *direct* bandgap was found for $\text{Cs}_2\text{AgInCl}_6$, in which both VBM and CBM extrema rest in the middle of the Brillouin zone (Γ -point) (Figure 4i). Square modulus of the electronic wave functions indicated that CBM was mostly derived from the $\text{In-}5s/\text{Ag-}5s$ and $\text{Cl-}3p$ states, while the VBM comprised $\text{In-}4d/\text{Ag-}4d$ and $\text{Cl-}3p$ states; non-occupied $\text{In-}5s$ orbitals were also seen at these states (Figure 4j). This configuration strongly correlated with the *direct* characteristic of the compound's bandgap. Calculating the effective masses of the carriers for

Figure 4: (a) Crystal structure of $\text{Cs}_2\text{CuSbCl}_6$ double perovskite [97]. Copyright 2020, American Chemical Society (b) XRD patterns of $\text{Cs}_2\text{CuSbCl}_6$ nanocrystals [97]. Copyright 2020, American Chemical Society (c) Absorption spectrum of $\text{Cs}_2\text{CuSbCl}_6$ nanocrystals [97]. Copyright 2020, American Chemical Society Inset: Corresponding Tauc plot of $\text{Cs}_2\text{CuSbCl}_6$ nanocrystals. (d) Nanosecond transient absorption (TA) signal of $\text{Cs}_2\text{CuSbCl}_6$ nanocrystals [97]. Copyright 2020, American Chemical Society (e) Electronic band structure of $\text{Cs}_2\text{CuSbCl}_6$. (f) PDOS of $\text{Cs}_2\text{CuSbCl}_6$ double perovskite [97]. Copyright 2020, American Chemical Society (g) UV-Vis absorbance of $\text{Cs}_2\text{AgInCl}_6$ in ambient and (h) under UV illumination (right) [100]. Copyright 2017, American Chemical Society. (i) Band structure of $\text{Cs}_2\text{AgInCl}_6$ double perovskite [100]. Copyright 2017, American Chemical Society. (j) Isosurface plots of $\text{Cs}_2\text{AgInCl}_6$ double perovskite [100]. Copyright 2017, American Chemical Society. (k) Normalized $\text{Cs}_2\text{AgInCl}_6$ PL spectrum of $\text{Cs}_2\text{AgInCl}_6$ double perovskite as a function of time [100]. Copyright 2017, American Chemical Society. (l) Calculated band structure and (m) PDOS of $\text{Cs}_2\text{AgInCl}_6$ double perovskite [103]. Copyright 2017 American Chemical Society.

$\text{Cs}_2\text{AgInCl}_6$ disclosed an electron effective mass of $0.29 m_e$ and hole effective mass of $0.28 m_e$. Non-dispersive band between Γ - and X -points (Figure 4i and j) created a 2D confined wave function within the material. Most likely, this flat band would be a feasible state for deep defects formation that prevents efficient charge carrier transport in the material.

From the PL characterization on $\text{Cs}_2\text{AgInCl}_6$ powders, a well-defined peak at 608 nm (2.04 eV) was identified (Figure 4k), which experienced a red-shift over a 100 ns timescale. This trend suggested the sub-bandgaps filling as mentioned above. However, the magnitude of measured bandgap from the PL spectrum fell around 1.26 eV lower

than the one calculated from UV-Vis reflection. Understanding this discrepancy, Meng et al. [103] discussed that this mystery PL emission can be explained by a parity-forbidden transition between the VBM and CBM at the Γ -point. The fountainhead of this feature rooted in the centrosymmetry of the material and contribution of the unoccupied In-5s orbitals in the CBM. Similar behaviour has been explored in other $\text{Cs}_2\text{B}^+\text{B}^{3+}\text{X}_6$ double perovskites ($\text{B}^+ = \text{group IA or IB}$, $\text{B}^{3+} = \text{In}^{3+} \text{ or } \text{Ga}^{3+}$) [104, 105]. One point missing in the previous reports was considering the O_h^5 symmetry with an inversion centre in double perovskites with $Fm\bar{3}m$ space group. The inversion centre could have critical effects on the optical transitions in the compound.

Meng et al. [100] obtained a calculated bandgap of 2.1 eV, around 1.0 eV smaller than that observed from UV-Vis spectroscopy. They found that VBM of the composition was as a result of Ag-4d/Cl-3p antibonding states, while the CBM was dominantly composed of delocalized In-5s states (Figure 4l and m). They thoroughly discussed that a combination of In-5s states and inversion symmetry (O_h) at the CMB gave a representation of $A_{1g}(\Gamma_1^+)$ to these states. On the other hand, at the VBM, Ag-4d orbitals had the highest energy, which determined the representation of $E_g(\Gamma_3^+)$ for the VBM at the Γ -point. In the end, it was seen that in $\text{Cs}_2\text{AgInCl}_6$ both VBM and CBM contained even parity that caused a parity-forbidden transition between these bands at the Γ -point. This phenomenon has been also reported for other semiconductors with inversion symmetry (e.g. $\text{CuM}^{\text{III}}\text{O}_2$ ($M = \text{Al, Ga, In}$) [106], Ti_2O_3 [107], SnO_2 [108], In_2O_3 [109]).

3.2 $\text{Cs}_2\text{AgTlX}_6$ ($X = \text{Cl}^-, \text{Br}^-$)

Unlike halide perovskites, in which the most explored method to tune the bandgap is the substitution of the halide in the structure, Slavney et al. demonstrated significant bandgap engineering in MHDPs. This was done through the energy alignment between the frontier orbitals of B^+ and B'^{3+} cations of the nominal $A_2BB'X_6$ double perovskite structure [110]. This strategy allowed the formation of $\text{Cs}_2\text{AgTlX}_6$ ($X = \text{Cl, Br}$) double perovskites with much smaller bandgaps than those of Pb-based perovskites with the same halide anion [110]. $\text{Cs}_2\text{AgTlBr}_6$ owns the smallest bandgap since the discovery of the halide perovskite family from 1883 [111]. XRD characterization on the products of $\text{Cs}_2\text{AgTlX}_6$ ($X = \text{Cl, Br}$) confirmed cubic structure in $Fm\bar{3}m$ space group, forming a 3D skeleton of alternating corner-sharing halide octahedra centred by Ag^+ and Tl^{3+} (Figure 5a). The optical absorption measurements revealed *direct* bandgaps of 1.96 and 0.95 eV for $\text{Cs}_2\text{AgTlCl}_6$ and $\text{Cs}_2\text{AgTlBr}_6$, respectively (Figure 5b and c). As compared to Cl-based (2.5–3.3 eV) [100, 112] and Br-based (1.8–2.3 eV) [113–115] halide perovskite counterparts, the obtained bandgap values for $\text{Cs}_2\text{AgTlCl}_6$ and $\text{Cs}_2\text{AgTlBr}_6$ were strongly red-shifted, such that $\text{Cs}_2\text{AgTlBr}_6$ bandgap was notably narrower than the typical I-based halide perovskites (1.2–1.6 eV) [116–118]. Despite the promising calculated bandgaps, similar to $\text{Cs}_2\text{AgInCl}_6$, no PL emission was observed for both compositions even at a low temperature of 20 K. Determining the transition dipole matrix elements for $\text{Cs}_2\text{AgTlCl}_6$ indicated an identically zero dipole matrix elements at the Γ -point and along the $\Gamma - X$ direction. This represented a category of symmetry-forbidden transitions (Figure 5d), similar to the observed phenomenon in $\text{Cs}_2\text{AgInCl}_6$. However, going away

from the Γ -point and along the $\Gamma - X$ direction and also along other lines in a reciprocal symmetry, the dipole matrix elements rapidly elevated. It meant that at energy levels higher than bandgap transitions were allowed. Therefore after excitation, charge carriers relaxed into the forbidden region. Since the energy-width of this region (170 meV) (Figure 5e) was greater than the activation energy at room temperature (26 meV), carriers were confined to the forbidden zone and cannot provide radiative recombination. This explained the lack of PL emission for the proposed compounds. These characteristics led to the long carrier recombination lifetimes in μs scale (Figure 5f). DFT calculation (Figure 5g) revealed that the small bandgap of the compounds was contributed by two factors: (i) Wide dispersion in the conduction band due to an overlap between the Tl-6s/Ag-5s orbitals with the halide orbitals that led to the small electron effective mass in this region (Table 2). Highly dispersive bands drove the band spectra towards each other, which strongly narrowed the compounds' bandgap. (ii) Another reason should be inherited from the little intrinsic energy-gap between filled Ag-4d states at VBM and vacant Tl-6s states at CBM. In $\text{Cs}_2\text{AgTlX}_6$ ($X = \text{Br, Cl}$), the CBM mostly contained Tl-6s with a minor portion for Ag-5s orbitals, while the VBM was ruled by Ag-4d orbitals (Figure 5g). Hence, a metal-to-metal charge transfer (MMCT) could be considered for their bandgap transition, which was a predominant pattern for many MHDPs [119]. These results emphasize the role of energy-gap between the frontier orbitals of the monovalent and trivalent metal cations in determining the compound's bandgap. Considering $\text{Cs}_2\text{AgBiCl}_6$ [49, 50] and $\text{Cs}_2\text{Tl}^+\text{Ti}^{3+}\text{Cl}_6$ [112] as the isostructures of the $\text{Cs}_2\text{AgTlCl}_6$, with bandgaps of 2.77 and 2.5 eV, respectively, they can give a better vision on this state. The greater bandgaps for these two compounds as compared to 1.96 eV for $\text{Cs}_2\text{AgTlCl}_6$ demonstrated that the combination of the monovalent (Ag^+, Tl^+) and trivalent (Bi^{3+} and Ti^{3+}) metal cations widely defined the bandgap value of the final product (Figure 5h).

3.3 $\text{MA}_2\text{TlBiBr}_6$

The ionic characteristic of halide (Cl^- and Br^-) bonds sparks off the unfavourable electronic properties in MHDPs namely wide bandgap. One possible strategy to enhance this drawback is to use Pearson- softer anions and monovalent cations at X^- and B^+ sites of the $A_2BB'X_6$ structure, respectively. Given this, Deng et al. in a deep computational work screened a series of hybrid MHDPs with the general formula of $\text{MA}_2B^+\text{BiX}_6$ where $B^+ = \text{K}^+, \text{Tl}^+, \text{Cu}^+, \text{Ag}^+$ and $X = \text{Cl}^-, \text{Br}^-$ and Γ^- . This triggered the synthesis of $\text{MA}_2\text{TlBiBr}_6$ as a new

member for the compositionally rich family of double perovskites [93]. Different from $\text{MA}_2\text{KBiCl}_6$, this new hybrid MHPD crystallized in the $Fm\bar{3}m$ space group following the typical ordering of the double perovskites with a bandgap of 2.16 eV (Figure 5i), which is proportional to that of MAPbBr_3 (2.2–2.35 eV) [120, 121]. Computed electronic band structures of the compound indicated curved band edges, in which VBM and CBM located at the Γ -point of the Brillouin zone given rise to the *direct* bandgap (Figure 5j). From PDOS calculations (Figure 5k), it was understood that the main contribution in the VBM belonged to $\text{Ti-}6s/\text{I-}5p$, $\text{Bi-}6s/\text{I-}5p$ antibonding states. Whereas the conduction band edge mostly consisted of $\text{Ti-}6s/\text{I-}5p$ bonding states and $\text{Bi-}6p/\text{I-}5p$ antibonding states. Altogether of these orbital interactions, at the Γ -point conduction band showed the lowest energy level. Consequently, both CBM and VBM of the compound lay down at the Γ -point resulting in a *direct* bandgap characteristic.

3.4 $\text{MA}_2\text{KBiCl}_6$ (B = Gd, Y)

To expand the family of hybrid MHPDs, Deng et al. demonstrated the first example of 3D rare-earth hybrid double

perovskites of $\text{MA}_2\text{KGdCl}_6$ and MA_2KYCl_6 , while previously the synthesis of some low-dimensional rare-earth hybrid perovskites have been reported [122, 123]. As found for $\text{MA}_2\text{KBiCl}_6$, these two compounds also crystallized in a rhombohedral ($R\bar{3}m$) symmetry at room temperature, in which the inorganic framework is a lattice of intermittent corner-sharing $(\text{BiCl}_6)^{3-}$ (B = Gd, Y) and $(\text{KCl}_6)^{5-}$ octahedra. The organic MA^+ cations were placed inside the inorganic cages (Figure 6a). The synthesis and characterization of these compounds were found to be effortful because both materials were deliquescent. However, their calculated positive decomposition enthalpies ($\Delta H_d = 23.52$ and 6.56 meV/atom for MA_2KYCl_6 and $\text{MA}_2\text{KGdCl}_6$) and negative formation enthalpies ($\Delta H_f = -949.48$ and -634.81 meV/atom for MA_2KYCl_6 and $\text{MA}_2\text{KGdCl}_6$) suggested that they were energetically favourable, similar to the inorganic rare-earth hybrid double perovskites [124]. A phase transition from the rhombohedral structure ($R\bar{3}m$) to the cubic structure ($Fm\bar{3}m$) was observed upon heating to 360–390 K for $\text{MA}_2\text{KGdCl}_6$ and 420–450 K for MA_2KYCl_6 (Figure 6b). Calculated electronic band structure of both rare-earth hybrid double perovskites gave large *direct* bandgaps of 4.91 eV for $\text{MA}_2\text{KGdCl}_6$ and 5.04 eV for MA_2KYCl_6 (Figure 6c). These large bandgap values were attributed to the

Figure 5: (a) Single-crystal structures of $\text{Cs}_2\text{AgBiBr}_6$ and $\text{Cs}_2\text{AgTlBr}_6$ double perovskites [110]. 2018 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (b) Tauc plot of $\text{Cs}_2\text{AgTlCl}_6$ and (c) $\text{Cs}_2\text{AgTlBr}_6$ double perovskites [110]. 2018 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (d) Transition dipole matrix elements $|P|^2$ along high-symmetry lines in reciprocal space. (e) Calculated absorption spectrum of $\text{Cs}_2\text{AgTlCl}_6$ showing the width of the symmetry forbidden region. (f) Time-resolved microwave conductivity traces of $\text{Cs}_2\text{AgTlCl}_6$ crystals [110]. 2018 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (g) Calculated band structure of $\text{Cs}_2\text{AgTlCl}_6$ [110]. 2018 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (h) Schematic representation of the relative energies of the atomic orbitals (lines) and bands (rectangles) for closely related double perovskites [110]. 2018 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (i) Corresponding Tauc plot of $\text{MA}_2\text{TlBiBr}_6$ hybrid double perovskite [93]. Copyright 2015, Royal Society of Chemistry. (j) Computed electronic band structure and (k) PDOS of $\text{MA}_2\text{TlBiBr}_6$ double perovskite [93]. Copyright 2015, Royal Society of Chemistry.

attendance of Cl^- with smaller ionic radius and higher electronegativity than bromine or iodine, and also the substantial ionic nature of the K^+ cation [93]. Assessing the contributed orbitals to the band-edges confirmed the dominant presence of the $\text{Cl-}3p$ nonbonding states at the VBM for both compounds, whereas the CBM was characterized by $\text{Gd-}5d/\text{Cl-}3p$ and $\text{Y-}4d/\text{Cl-}3p$ bonding states for $\text{MA}_2\text{KGdCl}_6$ and MA_2KYCl_6 , respectively (Figure 6d). On the other hand, MA^+ and K^+ cations showed a localized energy state that energetically inactivated them to subscribe to the band edges, similar to $\text{MA}_2\text{KBiCl}_6$ [88]. Unlike other transition-hybrid MHPDs (e.g. $\text{MA}_2\text{TlBiBr}_6$) [110], whose *direct* bandgap was strongly dependent on the $\text{Tl-}6s$ lone pairs, in rare-earth hybrid double perovskites of $\text{MA}_2\text{KBiCl}_6$ ($\text{B} = \text{Gd}, \text{Y}$) *direct* characteristic of the bandgap originated from the predominant role of $\text{Cl-}3p$ nonbonding states at the VBM. A *direct* bandgap is an important material characteristic to fulfil its potential for optoelectronic applications as it provides straightforward optical absorption and emission processes.

Although the calculated bandgaps for these proposed rare-earth hybrid halide double perovskites were extensively wide and unsuitable for solar cells, it was believed that doping some other rare-elements such as Tb^{3+} , Ce^{3+} or Eu^{3+} into the structure could further improve their potential as solid-state lighting [125].

4 Bandgap engineering of MHPDs

Although MHPDs have emerged as promising new alternatives for optoelectronic applications [48–50, 76, 88, 90, 100], in most cases, they have shown either large and *indirect* or *direct* forbidden bandgaps that practically are not satisfying for high-efficiency photovoltaics [103]. Though some computational works have predicted the potential solutions when both metal cations possess lone-pair frontier orbitals (e.g. $\text{Cs}_2\text{InBiCl}_6$ and $\text{Cs}_2\text{InSbCl}_6$) [126], experimental results confirmed their difficult formation at

Figure 6: Conventional unit cells of rhombohedral $\text{MA}_2\text{KBiCl}_6$ ($\text{B} = \text{Gd}$ and Y) at room temperature viewed (a) along the c -axis and (b) parallel to the a - b plane [122]. Copyright 2017 American Chemical Society. (c) Volumes per formula unit (f.u.) of $\text{MA}_2\text{KGdCl}_6$ and MA_2KYCl_6 upon heating [122]. Copyright 2017 American Chemical Society. (d) Calculated band structures and (e) PDOS for $\text{MA}_2\text{KGdCl}_6$ and MA_2KYCl_6 [122]. Copyright 2017 American Chemical Society. Indirect Tauc plots of (e) $\text{Cs}_2\text{Ag}(\text{Bi}_{1-x}\text{In}_x)\text{Br}_6$ and (f) $\text{Cs}_2\text{Ag}(\text{Bi}_{1-x}\text{Sb}_x)\text{Br}_6$ [130]. 2017 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (g) Photos of In- and Sb-alloyed $\text{Cs}_2\text{AgBiBr}_6$ samples. (h) PL spectra of In- and Sb-alloyed $\text{Cs}_2\text{AgBiBr}_6$ samples [130]. 2017 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (i) Calculated band structure of $\text{Cs}_2\text{AgBiBr}_6$, $\text{Cs}_2\text{Ag}(\text{Bi}_{0.75}\text{Sb}_{0.25})\text{Br}_6$, and hypothetical $\text{Cs}_2\text{AgSbBr}_6$ [130]. 2017 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (j) Calculated band structure of $\text{Cs}_2\text{Ag}(\text{Bi}_{1-x}\text{In}_x)\text{Br}_6$ with $x = 0.25, 0.50$ and 0.75 . (k) Optical images of $\text{Cs}_2\text{AgSb}_x\text{Bi}_{1-x}\text{Br}_6$ ($0 \leq x \leq 0.75$) thin-films [131]. 2019 Elsevier Ltd. All rights reserved. (l) Tauc plots of $\text{Cs}_2\text{AgSb}_x\text{Bi}_{1-x}\text{Br}_6$ ($0 \leq x \leq 0.75$) thin-films [131]. 2019 Elsevier Ltd. All rights reserved. (m) Averaged bandgap of $\text{Cs}_2\text{AgSb}_x\text{Bi}_{1-x}\text{Br}_6$ ($0 \leq x \leq 0.75$) thin-films [131]. 2019 Elsevier Ltd. All rights reserved.

room temperature [127]. Therefore, if MHDPs are expected to find a deserved position in the future of optoelectronics, their bandgap engineering is of vital importance. Atomic substitution has been shown as an effective method for tuning the bandgaps of semiconductors [128, 129]. In MHDPs with four various lattice sites in the $A_2BB'X_6$ structure, B^{3+} has the most diversity and freedom with more than 34 candidates to be placed at this site [76]. Given these, in this section, some reports on bandgap tuning of MHDPs are described.

4.1 Alloying in A_2AgBiX_6 ($A = MA^+$, Cs^+ ; $X = Cl^-$, Br^- and I^-)

4.1.1 In- and Sb-alloyed $Cs_2AgBiBr_6$

Bandgap engineering of $Cs_2AgBiBr_6$ is one approach to improve the material properties for enhancing its photovoltaic performance. Du et al. have demonstrated In^{3+} and Sb^{3+} alloying with the hosting material's structure ($Cs_2AgBiBr_6$) using the typical formula of $Cs_2Ag(Bi_{1-x}M_x)Br_6$ ($M = In, Sb$) [130]. In^{3+} could be incorporated in the Bi^{3+} lattice site up to 75% before the formation of the secondary phases, whereas Sb^{3+} substitution with lower homogeneity was limited to 37%. Diffuse reflection measurement revealed increment in the bandgap energy upon In^{3+} incorporation and decrement trend for Sb^{3+} adoption (Figure 6e and f). In particular, the bandgap of the hosting material enlarged from 2.12 to 2.27 eV while the In^{3+} doping proportion (x) increased from 0 to 0.75. In opposite, a bandgap reduction from 2.12 to 1.86 eV was observed for Sb^{3+} incorporation from 0 to 0.37, in agreement with the sample colour (Figure 6g). Regarding the PL emission, the In^{3+} -alloyed sample with $x = 0.25$ yielded the strongest PL intensity, while $x = 0.75$ showed the weakest (Figure 6h). Fitting the PL spectra indicated two Gaussian peaks at around 610–560 and 680 nm. The former shifted with the In^{3+} -alloying level and corresponded well with the band edge emission, whereas the latter with 1.8 eV energy smaller than the bandgap value might correlate with the defects into the band structure. The PL intensity reduction following more In^{3+} substitution should be due to the formation of deeper defects or a symmetry-forbidden for the transition from VBM to the CBM due to the presence of In-5s states in the CBM (Figure 6h) [103]. For Sb^{3+} -alloyed samples, a red-shift in the PL spectrum compared to the pure $Cs_2AgBiBr_6$ compound was clear (Figure 6h). The two fitted peaks for Sb^{3+} -substituted powders appeared to be at circa 775 nm (1.6 eV) and 905 nm (1.4 eV), which considerably fall lower than the measured bandgap for $x = 0.25$. This indicated the

formation of substantially deep defect states that could be counted for the fast PL emission intensity suppression.

DFT calculations showed for Sb^{3+} -alloyed samples with $x = 0.25$, VBM derived from Sb-5s/Ag-4d/Br-4p orbitals (Figure 6i), while the CBM formed by Sb-5p/Bi-6p orbitals. These orbital interactions yielded a 0.15 eV slip-down in the CBM and a 0.27 eV shift-up in the VBM forming an *indirect* bandgap. More adoption of the Sb^{3+} into the structure mitigated the incorporation of the Bi-6p states into the CBM and broadened the VBM. For In^{3+} -alloyed samples, the VBM originated from Bi-6s/Ag-4d/Br-4p orbitals; and the CBM came from In-5s/Bi-6p with a 0.13 eV drop in its energy level (Figure 6j). This fall came from the broadening of the In-5s-dominated CBM. At the same time, an energy fall in the VBM revealed a competing trend between the simultaneous downshifts in CBM and VBM. The final bandgap value was influenced by the winner of this competition. If the second trend outweighs the first one, the bandgap will increase that corresponded to the case of the experimental observations in this work. Inspired by these observations, Liu et al. developed a facile solution-processed approach to synthesis high purity $Cs_2AgSb_xBi_{1-x}Br_6$ ($0 \leq x \leq 0.75$) thin-films [131] with a maximum bandgap reduction of 0.25 eV from 2.22 to 1.97 eV for $x = 0.75$ (Figure 6k–m).

4.1.2 Tl-alloyed $Cs_2AgBiBr_6$

To produce a material with competitive photophysical properties to those of Pb-based halide perovskites ($MAPbI_3$), Slavney et al. demonstrated the dilute alloying of the $Cs_2AgBiBr_6$ with Tl^+ . Introducing TlBr into the precursor solution allowed the tuning of Tl^+ across the structure following the formula of $Cs_2(Ag_{1-a}Bi_{1-b})Tl_xBr_6$ ($0.003 < x = a + b < 0.075$). The products showed a nearly identical crystal structure to the hosting $Cs_2AgBiBr_6$ composition [132]. Determining the Tl oxidation state, X-ray absorption near-edge structure (XANES) measurement showed three inflection points on the rising edge of the compound with the Tl^{3+} spectrum, while for Tl^+ it was only in one point (Figure 7a). In general, it was observed that Tl can be positioned at either B^+ or B^{3+} sites, where in the dilute alloying regime of $0.003 < x < 0.075$, the substitution in B^{3+} site is dominant. UV–Vis measurement showed a sharp drop in the bandgap energy from *indirect* 1.95 eV for $x = 0$ to *direct* 1.72 eV or *indirect* 1.57 eV for $x = 0.010$ (Figure 7b and c). Further increasing x , a slower reduction was observed for the bandgap energy. At $x = 0.075$ as the highest alloying level, the bandgap reached to *indirect* 1.40 eV or *direct* 1.57 eV. Notably, this dilute alloying strategy brought the bandgap of $Cs_2AgBiBr_6$ within the acceptable range for single-junction photovoltaics. Time-resolved microwave photoconductivity (TRMC) measurements probed a

Figure 7: (a) X-ray near edge absorption structure (XANES) spectrum of $\text{Cs}_2(\text{Ag}_{1-x}\text{Bi}_{1-x})\text{Tl}_x\text{Br}_6$ ($x = 0.075$), Tl^+ and Tl^{3+} standards [132]. Copyright 2017, American Chemical Society. (b) Absorbance spectra of $\text{Cs}_2(\text{Ag}_{1-x}\text{Bi}_{1-x})\text{Tl}_x\text{Br}_6$ [132]. Copyright 2017, American Chemical Society. (c) Apparent bandgaps of $\text{Cs}_2(\text{Ag}_{1-x}\text{Bi}_{1-x})\text{Tl}_x\text{Br}_6$. (d) TRMC decay trace of $\text{Cs}_2(\text{Ag}_{1-x}\text{Bi}_{1-x})\text{Tl}_x\text{Br}_6$ (with $x = 0.075$) single-crystals [132]. Copyright 2017, American Chemical Society. Band structures of $\text{Cs}_2(\text{Ag}_{1-x}\text{Bi}_{1-x})\text{Tl}_x\text{Br}_6$ ($x = 0.06$) for (e) replacing Ag^+ with Tl^+ and (f) replacing Bi^{3+} with Tl^{3+} [132]. Copyright 2017, American Chemical Society. (g) XRD patterns for $\text{Cs}_2\text{AgSbCl}_6$ ($x = 0.00$) and for Cu^{2+} -doped $\text{Cs}_2\text{AgSbCl}_6$ materials [133]. Copyright 2018, American Chemical Society. (h) Schematic representation of the $\text{Cs}_2\text{AgSbCl}_6$ double perovskite structure and of possible Cu^{2+} -doped analogues [133]. Copyright 2018, American Chemical Society. (i) UV-Vis (solid lines) and normalized absorption (dotted lines) spectrum for $\text{Cs}_2\text{AgSbCl}_6$ parent ($x = 0.00$) and the maximum Cu^{2+} -doped ($x = 0.10$) materials [133]. Copyright 2018, American Chemical Society. (j) The Tauc plots of $\text{Cs}_2\text{AgSbCl}_6$ ($x = 0.00$) and (k) for the maximum Cu^{2+} -doped material ($x = 0.10$) [133]. (l) photographs of $\text{Cs}_2\text{AgSbCl}_6$ ($x = 0.00$) and Cu^{2+} -doped polycrystalline materials [133]. Copyright 2018, American Chemical Society.

decrease in the carrier lifetime in the alloyed compound, however still in the long-lived microsecond range (Figure 7d). This suggested that dopants did not form intensive recombination trap states, therefore carriers could expeditiously transfer in a solar cell structure.

DFT calculations helped to specify the electronic structure evolution of the compound after Tl-alloying. Ag^+ replacement by Tl^+ , a *direct* bandgap with a reduction of ca. 0.1 eV was observed (Figure 7e). Whereas considering Tl^{3+} substitution for Bi^{3+} , much larger bandgap shrinkage of 0.8 eV with an *indirect* transition was obtained (Figure 7f). A possible model to explain these different bandgap reductions can be that at low doping levels of Tl^+ , defect levels are extracted from Tl^{3+} -6s² and 6p⁰ orbitals, whereas substitution of Tl^{3+} introduces defect levels from Tl^{3+} -5d¹⁰ and 6s⁰ orbitals. By Tl^{3+} substitution, the average energy of the Tl^{3+} -6s⁰ orbitals is below the CBM of pure $\text{Cs}_2\text{AgBiBr}_6$, which, therefore, results in a considerable bandgap

reduction. This new band is dominated by Tl^{3+} -6s⁰ and Ag-4d orbitals that place the CBM at the L-point. On the other hand, Tl^+ substitution for Ag^+ , the average energy of the occupied Tl^+ -6s² orbitals is above the hosting compound's VBM, which slightly narrows the bandgap. Equal substitution of B⁺ and B³⁺ sites with Tl^+ and Tl^{3+} , the CBM is dominantly derived from the lower-energy Tl-6s states, which ultimately maintains the *indirect* characteristic of the bandgap.

4.2 Doping and alloying in $\text{Cs}_2\text{AgSbX}_6$ ($\text{X} = \text{Cl}^-$ and Br^-)

4.2.1 Cu-doped $\text{Cs}_2\text{AgSbCl}_6$

To mitigate the poor alignment of the most double perovskites' absorption profile with the solar spectrum,

Karmakar et al. [133] presented a dramatic red-shift in the bandgap energy of $\text{Cs}_2\text{AgSbCl}_6$ through Cu^{2+} doping. As discussed before, $\text{Cs}_2\text{AgSbCl}_6$ has an *indirect* bandgap transition, where the VBM and CBM mainly include Ag-4d/Cl-3p and Sb-5p/Cl-3p orbitals, respectively. A dilute incorporation of $3d^9$ states around the compound's VBM may narrow the bandgap while the 3D structural framework maintained unaltered. Heterovalent Cu^{2+} doping can be a potential strategy to reach this goal. To this end, Cu^{2+} was doped into the polycrystalline $\text{Cs}_2\text{AgSbCl}_6$ through solvent synthesis to produce the product with nominal formula of $\text{Cs}_2\text{Ag}_{1-a}\text{Sb}_{1-b}\text{Cu}_x\text{Cl}_6$ ($2x = a + b$, $x = 0.00, 0.01, 0.05, 0.10$). XRD characterizations showed a nearly identical spectrum for samples before and after doping that confirmed the formation of a fairly single-phase crystalline solid (Figure 7g). However, closer examination indicated an increase in the AgCl concentration by incorporating more Cu^{2+} into the structure. Qualitatively, it was speculated that upon Cu^{2+} -doping $[\text{AgCl}_6]^{5-}$ octahedra in the lattice were substituted by $[\text{CuCl}_6]^{4-}$ octahedra that yielded to the formation of vacancies to maintain charge neutrality. This caused some part of AgCl remained insoluble. In principle, Cu^{2+} can be incorporated into three sites of the hosting compound's crystal lattice: (i) Replacing the $[\text{AgCl}_6]^{5-}$ octahedra or (ii) the $[\text{SbCl}_6]^{3-}$ octahedra with $[\text{CuCl}_6]^{4-}$ octahedra (Figure 7h). (iii) Occupying the centre of the cuboctahedra (A-site) of the lattice that induced the formation of a neighbouring vacancy (Figure 7h).

UV-Vis reflection measurement (Figure 7i) illustrated a drastic red-shift of the compound's optical band edge after Cu^{2+} doping with a bandgap shrinkage of $\text{Cs}_2\text{AgSbCl}_6$ from 2.65 to 1.02 eV upon 1% ($x = 0.010$) Cu^{2+} -doping (Figure 7j–k). This was consistent with the dramatic visual colour change from yellow to black upon inducing more Cu^{2+} into the structure (Figure 7l). A similar trend has been observed in Tl-alloyed $\text{Cs}_2\text{AgBiBr}_6$ [132], Cu^{2+} -alloyed $\text{Cs}_4\text{Sb}_2\text{MnCl}_{12}$ material [134] and Pb-free $\text{MA}_2\text{CuCl}_x\text{Br}_{4-x}$ hybrid perovskites [135]. A band tailing characteristic in the Tauc plot of the doped samples suggested the formation of defects in the structure. In low doping amounts, a localized state in the vicinity of the band edges formed corresponding to a localized transition. Whereas, higher doping concentration caused a reduction in the average Cu–Cu distances between defect sites, therefore the localized impurity states converted to delocalized states, igniting more bandgap reduction by more Cu^{2+} doping.

4.2.2 In-alloyed $\text{Cs}_2\text{AgSbCl}_6$

Normally, it is not feasible to separately adjust the CBM and VBM, because they are practically antibonding and paired

bonding. However, in double perovskites ($\text{A}_2\text{BB}'\text{X}_6$), it is possible because in this structure $\text{B}^{+}\text{-}d^{10}$ states establish the VBM, and $\text{B}^{3+}\text{-}s/p$ states make up the CBM. To develop a systematic strategy for an *indirect* to *direct* bandgap convergence in MHDPs, Tran et al. [92] presented a rational design approach. The idea was based on regulating the electron configuration of the B^{3+} site in $\text{A}_2\text{BB}'\text{X}_6$ structure from s^0 to s^2 states. This strategy could adjust the main contributed states at CBM between s-orbitals and p-orbitals while the remainder of the band structure maintained intact. Studying optoelectronic properties of $\text{Cs}_2\text{AgSbCl}_6$, $\text{Cs}_2\text{AgInCl}_6$ and intermediate $\text{Cs}_2\text{AgSb}_x\text{In}_{1-x}\text{Cl}_6$ polycrystalline samples helped to understand the viability of this hypothesis. UV-Vis diffuse reflectance spectra characterization showed *indirect* bandgap of 2.54 eV for $\text{Cs}_2\text{AgSbCl}_6$, as discussed thoroughly in the previous sections [92], and a *direct* bandgap of 3.53 eV for $\text{Cs}_2\text{AgInCl}_6$. An *indirect* to *direct* transition was observed by replacing 60% of Sb^{3+} with In^{3+} ($\text{Cs}_2\text{AgSb}_{0.4}\text{In}_{0.6}\text{Cl}_6$, $x = 0.4$). From the corresponding Tauc plot, it was seen that at $x = 0.5$ the compound indicated a very platy absorption spectrum starting at the edge of 2.81 eV. A following sharper absorption at 3.12 approximated the bandgap of 2.81 eV for this ratio of Sb:In (4:6) (Figure 8a). Further inducing In^{3+} in the structure, the characteristic of the *direct* bandgap appeared in their relevant spectrum. Figure 8b depicts the phase-diagram of the bandgap of the $\text{Cs}_2\text{AgSb}_x\text{In}_{1-x}\text{Cl}_6$ ($x = 0, 0.2, 0.4, 0.5, 1$) that clearly shows the bandgap transition from *indirect* to *direct* having more In^{3+} in the composition. The reason for this was attributed to an alternation in the characteristic of the CBM from s-orbital-derived feature to p-orbital-derived one. This observation confirmed the convergence of *direct* and *indirect* bandgaps in double perovskites through the adjustment of the CBM characteristics.

4.3 Doping and alloying in $\text{Cs}_2\text{AgInCl}_6$

4.3.1 Mn-doped $\text{Cs}_2\text{AgInCl}_6$

To tune the optical properties of MHDPs, Nandha et al. imparted the visible-light emission property in $\text{Cs}_2\text{AgInCl}_6$ through Mn^{2+} doping [136]. XRD characterization on samples with different amounts of Mn^{2+} in the precursor exhibited no new peak, inferring the formation of no impurity phase related to Mn (Figure 8c). Also, no additional peak of AgCl could be found that indicated the full reaction of AgCl in the precursor. Besides, the XRD spectra exhibited no discernible displacement of the peaks that confirmed the negligible impact on the crystal structure. UV-Vis measurement indicated the variation of absorption edge upon Mn^{2+} -doping

(Figure 8d). This highlighted no significant change in the absorption of the parent material after Mn-doping, where the colour of the powders with 0 and 0.9% Mn remained in the similar white (Figure 8d, inset). PL measurement on the Mn-doped $\text{Cs}_2\text{AgInCl}_6$ powders showed weak PL spectra centred at ~ 619 nm. Interestingly, the PL intensity exhibited a significant increase upon Mn-doping, and the peak slightly shifted to ~ 632 nm (Figure 8e). These results emphasized the influence of Mn-doping on PL emission efficiency. Previous reports discussed the de-excitation of a Mn-*d*-orbital electron from the 4T_1 to 6A_1 state as the origin of the enhanced PL intensity in Mn-doped semiconductors [137–139]. Since this transition for Mn-*d* orbital electrons is spin-forbidden, a slow PL decay in the range of millisecond (ms) to sub-ms was expected for the doped samples, as shown in Figure 8f.

The long PL lifetimes of Mn-doped samples were obtained by a tri-exponential model, Figure 8f (inset). A PL enhancement of doped samples was ascribed to the weak interaction of 4T_1 – 6A_1 inner core atomic like transition with non-radiative trap states in $\text{Cs}_2\text{AgInCl}_6$ lattice [136, 140]. The PL emission intensity increased continuously up until 1% Mn doping; while further Mn content resulted in the reduction of PL intensity, possibly due to Mn–Cl–Mn exchange interactions [141].

4.3.2 Fe-alloyed $\text{Cs}_2\text{AgInCl}_6$

To tune the bandgap of the MHPDs, Yin et al. [142] demonstrated a new class of double perovskites by incorporation of Fe^{3+} in the parent structure of $\text{Cs}_2\text{AgInCl}_6$. This

Figure 8: (a) Tauc plots for $\text{Cs}_2\text{AgSb}_x\text{In}_{1-x}\text{Cl}_6$ ($x = 0, 0.2, 0.4, 0.5, 1$) [92]. Copyright 2015, Royal Society of Chemistry. (b) Phase diagram for $\text{Cs}_2\text{AgSb}_x\text{In}_{1-x}\text{Cl}_6$ ($x = 0, 0.2, 0.4, 0.5$ and 1) [92]. Copyright 2015, Royal Society of Chemistry. (c) XRD patterns for Mn-doped $\text{Cs}_2\text{AgInCl}_6$ with different Mn concentrations [136]. Copyright 2015, Royal Society of Chemistry. (d) UV–Vis absorption spectra of Mn-doped $\text{Cs}_2\text{AgInCl}_6$ with different Mn contents. Insets: the photographs of white colour powder samples under visible light [136]. Copyright 2015, Royal Society of Chemistry. (e) PL spectra of Mn-doped $\text{Cs}_2\text{AgInCl}_6$ with different Mn contents. Insets: the photographs of luminescence from the powder samples under UV light [136]. Copyright 2015, Royal Society of Chemistry. (f) PL decay dynamics of 0.3 and 0.9% Mn-doped $\text{Cs}_2\text{AgInCl}_6$ [136]. Copyright 2015, Royal Society of Chemistry. (g) Morphology of as-prepared $\text{Cs}_2\text{AgIn}_x\text{Fe}_{1-x}\text{Cl}_6$ ($0 \leq x \leq 1$) double perovskite single-crystals with different x values [142]. 2020 Wiley-VCH GmbH. (h) UV–Vis absorbance spectra of as-prepared $\text{Cs}_2\text{AgIn}_x\text{Fe}_{1-x}\text{Cl}_6$ ($0 \leq x \leq 1$) double perovskite single-crystals with different x values [142]. 2020 Wiley-VCH GmbH. (i) Bandgap alignment of $\text{Cs}_2\text{AgIn}_x\text{Fe}_{1-x}\text{Cl}_6$ ($0 \leq x \leq 1$) double perovskites [142]. 2020 Wiley-VCH GmbH. (j) PL spectra of as-prepared $\text{Cs}_2\text{AgIn}_x\text{Fe}_{1-x}\text{Cl}_6$ ($0 \leq x \leq 1$) double perovskite single-crystals with different x values. (k) TRPL spectra of $\text{Cs}_2\text{AgIn}_x\text{Fe}_{1-x}\text{Cl}_6$ ($0 \leq x \leq 1$) double perovskite [142]. 2020 Wiley-VCH GmbH.

triggered the successful development of a group of materials with the formula of $\text{Cs}_2\text{AgIn}_x\text{Fe}_{1-x}\text{Cl}_6$ ($0 \leq x \leq 1$) (Figure 8g). UV–Vis absorbance demonstrated a significant red-shift from 450 to 800 nm by increasing Fe^{3+} into the lattice (Figure 8h). This significant bandgap tuneability boosted various applications for $\text{Cs}_2\text{AgIn}_x\text{Fe}_{1-x}\text{Cl}_6$ ($0 \leq x \leq 1$) materials in optoelectronic and photovoltaic fields. Ultra-violet photoelectron spectroscopy (UPS) confirmed the evolution of the compound's band position, in which absolute replacement of In^{3+} with Fe^{3+} drives up the VBM from -5.39 to -4.80 eV, while at the same time shifts the CBM down from -2.48 to -3.25 eV (Figure 8i).

Fe^{3+} doping also resulted in the red-shift of PL spectra in $\text{Cs}_2\text{AgIn}_x\text{Fe}_{1-x}\text{Cl}_6$ ($0 \leq x \leq 1$) perovskite single-crystals. However, PL shifts did not show a consistent wavelength shift with the absorbance edge. In the case of $\text{Cs}_2\text{AgInCl}_6$ ($x = 0$), the spectrum peaked at 620 nm was attributed to the emission via self-trapped exciton recombination (Figure 8j). TRPL measurements revealed that the PL lifetime significantly decreased with increasing Fe^{3+} -doping, suggesting the variation of the PL mechanism in $\text{Cs}_2\text{AgIn}_x\text{Fe}_{1-x}\text{Cl}_6$ ($0 \leq x \leq 1$) perovskite family (Figure 8k). The shorter lifetime of the $\text{Cs}_2\text{AgIn}_x\text{Fe}_{1-x}\text{Cl}_6$ ($0 \leq x \leq 1$) compounds with more Fe^{3+} most likely was due to the fast dissociation of the trapped excitons to generate free electrons and holes. The broad solar absorption and efficient exciton dissociation suggested the great potential applications of the proposed structures for photovoltaics and photocatalysis.

5 Layered MHDPs

The creation of elpasolite-type MHDPs was a remarkable breakthrough due to: (i) the 3D framework of the metal halide octahedral, and (ii) the all-inorganic composition that is expected to preserve high stability. However, large indirect bandgaps hamper their implementation in photovoltaics. Kentsch et al. [143], by studying the exciton mechanism of this family of materials, reported the existence of a very high exciton binding energy and also a strong electron–phonon coupling similar to $\text{Cs}_3\text{Bi}_2\text{Br}_9$ and BiBr_3 . It is known that these features induced undesirable electron-hole recombination that severely barricaded efficient carrier transport. Dimensional reduction or structural conversion entailed a dramatic shift in the compound's photophysical properties [144]. For instance, upon chemical exfoliation of MoS_2 from the bulk structure to a monolayer, an *indirect* to *direct* transition occurs in the material's bandgap [145, 146]. Analogously, dimensional reduction in the inorganic block of organic–inorganic hybrids affords material's electronic confinement, well represented by

Pb-halide perovskites [123, 147]. Double perovskites with a neat configuration of two different metal cations, can host various metals with different oxidation states. Although halide double perovskites have been studied back to the 1930s [148], their 2D compounds are still rare. Therefore, their photophysical and electronic changes induced by the reduction of structural dimension have remained fairly underexplored. This section presents the progress achieved to date in the layered MHDPs.

5.1 $\text{Rb}_4\text{Ag}_2\text{BiBr}_9$

Recently, Sharma et al. [149] indicated the formation of large single-crystals of a new all-inorganic non-toxic Bi-based semiconductor, $\text{Rb}_4\text{Ag}_2\text{BiBr}_9$, as the first-discovered composition in the quaternary Rb–Ag–Bi–Br phase diagram. Different from elpasolite-type MHDPs, this material crystallizes in the centrosymmetric space group of $Pn\bar{m}$ in which $(\text{BiBr}_6)^{3-}$ octahedra and $(\text{AgBr}_5)^{4-}$ square pyramids connected through edges and corners to complete a non-perovskite 2D layered structure. In this configuration, alternating polyanionic $[\text{Ag}_2\text{BiBr}_9]^{4-}$ layers are composed of alternating $[\text{BiBr}_4]^-$ and $[\text{Ag}_2\text{Br}_5]^{3-}$ sheets. In the $[\text{Ag}_2\text{Br}_5]^{3-}$ slab, $(\text{AgBr}_5)^{4-}$ square pyramids form an edge- and corner-shared network. These slabs are attached to $(\text{BiBr}_6)^{3-}$ octahedral by a corner-shared connection that ultimately yields the polyanionic $[\text{Ag}_2\text{BiBr}_9]^{4-}$ layers separated by Rb^+ cations (Figure 9a and b).

To investigate the photophysical properties of the newly designed material, UV–Vis reflection measurement indicated the well-defined absorptions at 2.82 and 3.23 eV (Figure 9c). One fact that could be deduced from the shape of the plot, whose tail gradually went off to the lower energies, was the existence of high defect concentration, similar to the case of most all-inorganic halide double perovskite [48, 49, 85, 150]. From the Tauc plots and adopting the *indirect* and *direct* fitting scenarios, bandgap energies of 2.38 (*indirect*) and 2.57 eV (*direct*) were elicited fall within the observed range of other MHDPs such as $\text{Cs}_2\text{AgBiX}_6$ ($\text{X} = \text{Cl}^-$ or Br^-) [48, 49, 85, 150]. Room-temperature PL spectrum of $\text{Rb}_4\text{Ag}_2\text{BiBr}_9$ (Figure 9d) specified two emission bands, one positioned at 2.36 eV featuring a weak and visible broadband emission (marked as P1), and a relatively intense one. The second narrow infrared emission comprising several peaks of P2, P3 and P4 settled at 1.52, 1.44 and 1.28 eV, respectively (Figure 9d). P1 emission agreed well with an indirect transition or trap emission, similar to the previous reports [48, 49, 85, 150]. Measuring the photoluminescence excitation (PLE) spectra at different emission energies of 2.36 and 1.55 eV (Figure 9d) showed a broad peak at 3.34 eV for the

Figure 9: (a) A polyhedral representation of the crystal structure of $\text{Rb}_4\text{Ag}_2\text{BiBr}_9$ [149]. Copyright 2019, American Chemical Society. (b) A top view of a segment of a $[\text{Ag}_2\text{BiBr}_9]^{4-}$ layer [149]. Copyright 2019, American Chemical Society. (c) Tauc plots of $\text{Rb}_4\text{Ag}_2\text{BiBr}_9$. The inset: the absorption spectrum of $\text{Rb}_4\text{Ag}_2\text{BiBr}_9$ [149]. Copyright 2019, American Chemical Society. (d) Room temperature PL spectrum (red solid line) and photoluminescence excitation (PLE) spectra of $\text{Rb}_4\text{Ag}_2\text{BiBr}_9$ single-crystals [149]. Copyright 2019, American Chemical Society. (e) Electronic band structures and (f) PDOS of $\text{Rb}_4\text{Ag}_2\text{BiBr}_9$ [149]. Copyright 2019, American Chemical Society. (g) Crystal structures of $\text{Cs}_4\text{CuSb}_2\text{Cl}_{12}$ and $\alpha\text{-Cs}_3\text{Sb}_2\text{Cl}_9$ [152]. Copyright 2017, American Chemical Society. (h) Absorbance spectrum of $\text{Cs}_4\text{CuSb}_2\text{Cl}_{12}$. Inset: Tauc plot of $\text{Cs}_4\text{CuSb}_2\text{Cl}_{12}$ [152]. Copyright 2017, American Chemical Society. (i) Calculated band structure (left) and DOS/PDOS (right) of $\text{Cs}_4\text{CuSb}_2\text{Cl}_{12}$ [152]. Copyright 2017, American Chemical Society. (j) Single-crystal X-ray structures of $(\text{BA})_4\text{AgBiBr}_8$, $(\text{BA})_2\text{CsAgBiBr}_7$ and $\text{Cs}_2\text{AgBiBr}_6$ [119]. Copyright 2018, American Chemical Society. Band structures corresponding of (k) $(\text{BA})_2\text{CsAgBiBr}_7$ and (l) $(\text{BA})_4\text{AgBiBr}_8$ [119]. Copyright 2018, American Chemical Society. (m) Low-temperature PL spectra and 7 K absorption spectrum of a film of $(\text{BA})_4\text{AgBiBr}_8$. Inset: Excitation power (mW/cm²) dependence of the emission intensity [119]. Copyright 2018, American Chemical Society. (n) The 14 K PL spectra of powders of $(\text{BA})_2\text{CsAgBiBr}_7$, $(\text{BA})_4\text{AgBiBr}_8$ and $\text{Cs}_2\text{AgBiBr}_6$ [119]. Copyright 2018, American Chemical Society.

former emission energy that was near the 3.23 eV absorption peak depicted in Figure 9c. For the 1.55 eV emission energy, PL spectra illustrated a peak at 2.82 eV, in excellent accordance with the low energy absorption peak in the absorption spectrum (Figure 9c). Given these, the 3.23 and 2.82 eV absorption peaks were ascribed to excitonic absorption fundamentally from two different species of $(\text{AgBr}_5)^{4-}$ and $(\text{BiBr}_6)^{3-}$.

Electronic band structure calculations showed the valence and conduction band edges positioned at the *U*- and *S*-points, respectively. This band configuration yielded an indirect bandgap of 1.69 eV and slightly larger direct bandgap of 1.70 eV (Figure 9e). Moreover, $\text{Rb}_4\text{Ag}_2\text{BiBr}_9$ showed a similar band structure to that of $\text{Cs}_2\text{AgBiX}_6$ ($\text{X} = \text{Cl}^-$, Br^-)

[48, 49, 85, 150] and $\text{Cs}_2\text{AgTlX}_6$ [151]. PDOS calculation revealed that the CBM was a mixture of the strong contribution of Bi-6p and smaller contribution of Br-4p orbitals, while the VBM consisted of antibonding Br-4p and Ag-4d orbitals (Figure 9f). Structurally, $(\text{BiBr}_6)^{3-}$ octahedra were isolated; hence, the conduction band states were spatially localized in $\text{Rb}_4\text{Ag}_2\text{BiBr}_9$ that caused a small dispersion in the conduction band. The wave function analysis of the compound's valence band showed a hybridization between the Br-4p and Ag-4d states that was extensively confined within the 2D plane upright to the *a*-axis. This highlights the quasi-2D nature of the $\text{Rb}_4\text{Ag}_2\text{BiBr}_9$ electronic structure with both valence band and conduction band featuring flat bands. The localized electronic states on both $(\text{BiBr}_6)^{3-}$ octahedra and

(AgBr₅)⁴⁻ square pyramids must elevate exciton localization. Therefore, optical excitation may generate Ag- and Bi-centred localized excitons [149].

5.2 Cs₄CuSb₂Cl₁₂

Vargas et al. [152] reported the first combination of divalent Cu²⁺ and trivalent Sb³⁺ metal cations to synthesize Cs₄CuSb₂Cl₁₂, with a triple-layered ($n = 3$) perovskite structure. Cu is the most reported transition metal to form 2D halide perovskites, some of which were used in solar cells, albeit with relatively low PCEs ($\leq 0.017\%$) [135]. Antimony (Sb) has some advantages of relatively low toxicity and the capability to form versatile structures of corner-sharing (SbX₆)³⁻ (X = Cl, Br, I) octahedral [153, 154] and halide perovskites [41, 123]. Besides, Sb³⁺ is isoelectronic with Sn²⁺ so an orbital overlap with Cu was expected, as presented in Cu–Sb chalcogenides with promising solar cell PCEs of up to 3.5% [155]. Although computationally the potential of Cu⁺–Sb³⁺ 3D halide double perovskites of Cs₂CuSbX₆ (X = Cl, Br and I) have been examined and proposed [50], using traditional solution-process approaches, there has been no access to such compounds yet. The combination of Cu²⁺–Sb³⁺ can be an option, however not suitable for 3D structure, as the sort of the metals' electron configuration renders a layered perovskite. Cs₄CuSb₂Cl₁₂ crystallizes in the monoclinic *C2/m* systems, in which alternating (CuCl₆)⁴⁻ and (SbCl₆)³⁻ octahedra attached through corner-sharing stack and Cs⁺ atoms rested at the voids in between the octahedra to form a $\langle 111 \rangle$ -oriented triple-layered ($n = 3$) framework (Figure 9g). This structure can also be conceived as a defective 3D perovskite architecture with vacancies generated by 3+ oxidation state of the Sb that administrated the structural breakage from 3D network to a 2D network.

Assessing the competency of Cs₄CuSb₂Cl₁₂ for photovoltaics, the optical absorption measurement implicated the semiconducting nature of the material with an impressive *direct* bandgap of 1.00 eV (Figure 9h). A semiconductor with this range of bandgap is well-fitted for single absorber solar cells, with a predicted PCE of 30.9% according to the Shockley–Queisser limit [156] or as the bottom operation layer in an all-perovskite tandem solar cell. Remarkably, the bandgap of Cs₄CuSb₂Cl₁₂ is 2.0 eV smaller than Cs₃Sb₂Cl₉ as the parent compound (3.00 eV), signifying a drastic bandgap reduction.

Electronic structure calculations of Cs₄CuSb₂Cl₁₂ confirmed the *direct* characteristic of the bandgap by positioning both VBM and CBM near the *E*-point of the Brillouin

zone (Figure 9i). Significant dispersion of the material's band structures in both directions of parallel and perpendicular to the layers acknowledged the material's capability for photovoltaics regardless of its layered structure [41, 123]. PDOS calculations showed that CBM was predominantly made by Sb-5*p* and Cl-3*p* orbitals. However, Cu²⁺ contribution to the CBM was found to be negligible. Therefore the considerable bandgap shrinkage of Cs₄CuSb₂Cl₁₂ should be mainly driven by the role of Cu²⁺ orbitals in the compound's VBM. It was found that the material's VMB was ran by Cu-3*d* and Cl-3*p* orbitals (Figure 9i). The appropriate orbital-overlap between Cu-3*d* and the Cl-3*p*/Sb-5*p* orbitals broadened the VBM that ultimately reduced the bandgap. The presence of a Cu-3*d*⁹ also raised partly occupied states at VBM that could generate further charge carriers. One of the key factors for solar cell performance is the charge carrier mobility of the absorbing layer that is closely related to the hole and electron effective masses of the material. The calculated hole and electron effective masses for Cs₄CuSb₂Cl₁₂ were determined to be 0.16*m_e* and 0.32*m_e*, respectively, comparable to those of MAPbI₃ [157], and suggesting high carrier mobility of Cs₄CuSb₂Cl₁₂.

5.3 (BA)₄AgBiBr₈ and (BA)₂CsAgBiBr₇

The 3D lattice of halide perovskites (A⁺B²⁺X₃) accommodates corner-sharing B–X octahedra, in which cuboctahedral cavities are engaged by small cations at the A-site [158]. Introducing larger organic cations to these cavities partitions the ordered 3D structure into the 2D structure of A₂B²⁺X₄, that is composed of corner-sharing B–X octahedra in a single-sheet order ($n = 1$). These sheets are separated by regular arrays of large organic cations [159]. The thin inorganic sheets can be tuned to thicker ones by mixing small and large A-site cations that generate the general formula A'₂A_{*n*-1}B_{*n*}X_{3*n*+1} ($\infty > n \geq 1$; A' = large organic cation, A = small inorganic cation) [160]. In this regard, Connor et al. [119] explored the viability of layered MHDPs by synthesizing (BA)₄AgBiBr₈ and (BA)₂CsAgBiBr₇ (BA = CH₃(CH₂)₃NH₃⁺) as the layered derivatives of Cs₂AgBiBr₆.

(BA)₄AgBiBr₈ showed a typical $n = 1$ perovskite structure with the generic formula of A'₂B⁺_{0.5}B³⁺_{0.5}X₄ × 2 where Ag⁺ and Bi³⁺ regularly occupy the B⁺ and B³⁺ sites to form monolayer inorganic parts. By incorporating both inorganic cation of Cs⁺ (A-site) and organic cation of BA⁺ (A'-site), a product with the formula of A'₂AB⁺B³⁺X₇ was attained, however, with heavy distortion particularly at the Ag⁺-site (Figure 9j). Similar to halide perovskites, this combination gave rise to the formation of thicker inorganic

sheets with two inorganic layers of Ag^+ and Bi^{3+} octahedra arranged in all three dimensions ($n = 2$) (Figure 9j). In this configuration, small Cs^+ cations resided in the cuboctahedra cavities of the lattice, whereas bilayers of the large organic cation (BA^+) templated the inorganic slabs in a monoclinic lattice.

To explore the electronic consequences of the dimensional reduction in the proposed compounds, DFT calculations showed the band structure of $(\text{BA})_2\text{CsAgBiBr}_7$ (Figure 9k) was very similar to $\text{Cs}_2\text{AgBiBr}_6$. This indicated the orbital compositions of the VBM with Ag-4d, Br-4p and Bi-6s characteristics at the A-point and the CBM with an Ag-5s, Br-4p and Bi-6p characteristics at the B-point resulting the *indirect* bandgap of 2.96 eV. Accordingly, the key band structure characteristics of $(\text{BA})_2\text{CsAgBiBr}_7$ directly came from $\text{Cs}_2\text{AgBiBr}_6$. In contrast, there was a great difference between the band structure of $(\text{BA})_4\text{AgBiBr}_8$ and $\text{Cs}_2\text{AgBiBr}_6$. In $(\text{BA})_4\text{AgBiBr}_8$ system, the VBM almost entirely came from the Ag-4d and Br-4p states, while Bi-s orbitals showed very little contribution. The compound's CBM encompassed only Bi-6p and Br-4p orbitals with all Ag-5s orbitals sitting at higher energy levels. This concluded *direct* bandgap of 3.01 eV for $(\text{BA})_4\text{AgBiBr}_8$ (Figure 9l). It was discussed that the simultaneous contribution of the Ag and Bi frontier orbitals in both the valence band and the conduction band manipulated the *indirect* bandgap in $\text{Cs}_2\text{AgBiBr}_6$ [47, 49, 132, 161]. Avoiding this hybridization in $(\text{BA})_4\text{AgBiBr}_8$, a single-metal-orbital characteristic at the compound's band edges was observed. This *indirect* to *direct* transition due to dimensional reduction was reminiscent of the exfoliation impacts in transition-metal dichalcogenides [145, 146].

PL measurement of $(\text{BA})_4\text{AgBiBr}_8$ thin-film showed a weak and broad PL spectrum at 20 K that rapidly quenched at higher temperatures (Figure 9m). Unlike the excitonic PL from Pb–Br halide perovskites that indicates superlinear behaviour [162, 163], the luminescence intensity of $(\text{BA})_4\text{AgBiBr}_8$ thin-film possessed a sub-linear dependence on the power density of the incident laser. This signified a defect-mediated radiative recombination source in the material. The PL measurement on $(\text{BA})_2\text{CsAgBiBr}_7$ demonstrated three broad luminescence characteristics, two of them strongly agreed the PL from $(\text{BA})_4\text{AgBiBr}_8$ ($n = 1$) and $\text{Cs}_2\text{AgBiBr}_6$ ($n = \infty$) (Figure 9n). Similar to Pb–I halide perovskite films with $n > 1$, where PL displayed features from multiple “ n ” values [164], this observation may come from the domination of $(\text{BA})_4\text{AgBiBr}_8$ ($n = 1$) and $\text{Cs}_2\text{AgBiBr}_6$ ($n = \infty$) within the $(\text{BA})_2\text{CsAgBiBr}_7$ ($n = 2$) structure or from similar defect-mediated emission in all these compounds.

5.4 $\text{Cs}_{3+n}\text{M}^{2+}_n\text{Sb}_2\text{X}_{9+3n}$ ($\text{M} = \text{Sn}^{2+}, \text{Ge}^{2+}$)

Although MHPDs have a 3D framework, they do not show high electronic dimensionality that is necessary for an efficient photovoltaic absorber [165]. Given this, Tang et al. computationally proposed a general approach to produce layered halide double perovskites with the formula of $\text{Cs}_{3+n}\text{M}^{2+}_n\text{Sb}_2\text{X}_{9+3n}$ ($\text{M}^{2+} = \text{Sn}, \text{Ge}$) as promising light absorbers with high electronic dimensionality (Figure 10a) [166]. The parent material in this study was $\text{Cs}_3\text{Sb}_2\text{I}_9$. Appraising different cations for M^{2+} site of the proposed structure, Sn^{2+} and Ge^{2+} were first selected, because of their low toxicity and also their isoelectronic structure with Sb^{3+} . Calculating the band structures of the hypothetical-layered MHPDs of $\text{Cs}_4\text{M}^{2+}\text{Sb}_2\text{I}_{12}$ ($\text{M}^{2+} = \text{Cu}, \text{Sn}, \text{Ge}$) and hosting material of $\text{Cs}_3\text{Sb}_2\text{I}_9$ revealed that for $\text{Cs}_3\text{Sb}_2\text{I}_9$, the VBM mainly comprised antibonding Sb-5s and I-5p states, and the CBM mostly came from Sb-5p states (Figure 10b). For the case of hypothetical $\text{Cs}_4\text{CuSb}_2\text{X}_{12}$, since Cu has a +2 oxidation state with the $3d^9$ outer electron configuration, a hybridization occurred between the partially vacant Cu-3d and I-5p states. This created a localized conduction band below the Sb-5p orbitals that generated considerably large electron effective mass (i.e. $m_{\text{electron}} = 6.97 m_e$, $m_{\text{hole}} = 1.09 m_e$ for $\text{Cs}_4\text{CuSb}_2\text{Cl}_{12}$). Therefore, although $\text{Cs}_4\text{CuSb}_2\text{X}_{12}$ ($\text{X} = \text{I}, \text{Br}, \text{Cl}$) layered double perovskites showed narrower bandgaps, they offered less promise for photovoltaics. Considering other divalent cations with ns^2 electron configuration ($\text{Sn}^{2+}, \text{Ge}^{2+}$) should be an advantageous approach to enhance the photovoltaic-relevant characteristics. The calculations confirmed that hypothetical $\text{Cs}_4\text{SnSb}_2\text{I}_{12}$ and $\text{Cs}_4\text{GeSb}_2\text{I}_{12}$ layered MHPDs owned *direct* bandgaps of 1.66 and 1.76 eV, respectively, that were notably smaller than the hosting compound of $\text{Cs}_3\text{Sb}_2\text{I}_9$ (Figure 10c). Additionally, in contrary to Cu^{2+} analogue, these compounds presented rather dispersive CBMs largely drew out of Sn-5p or Ge-4p and Sb-5p states (Figure 10b). This dispersive characteristic of conduction band yielded smaller electron effective masses for $\text{Cs}_4\text{GeSb}_2\text{I}_{12}$ and $\text{Cs}_4\text{SnSb}_2\text{I}_{12}$ than those of $\text{Cs}_3\text{Sb}_2\text{I}_9$ and $\text{Cs}_4\text{CuSb}_2\text{Cl}_{12}$ calculated in this work (Table 2). For the $\text{Cs}_3\text{Sb}_2\text{I}_9$, the VBMs of $\text{Cs}_4\text{SnSb}_2\text{I}_{12}$ and $\text{Cs}_4\text{GeSb}_2\text{I}_{12}$ experienced a 0.44 and 0.19 eV shift-up, respectively, that was due to the higher energy-lying Sn-5s and Ge-4s orbitals. Regarding the compounds CBM, in $\text{Cs}_4\text{SnSb}_2\text{I}_{12}$, this band slightly went up by 0.07 eV, while the case for $\text{Cs}_4\text{GeSb}_2\text{I}_{12}$ was a 0.08 eV shift-down. Therefore, bandgap reduction of the new compounds was dominated by the higher energy level of Sn-5s and Ge-4s states in their VBMs. Figure 10c shows the great improvement of the compounds' optical absorption as compared to parent material by inserting $[\text{SnI}_6]^{4-}$ or $[\text{GeI}_6]^{4-}$ octahedra into the $[\text{Sb}_2\text{I}_9]^{3-}$ bilayers. Interestingly, although

$\text{Cs}_4\text{CuSb}_2\text{Cl}_{12}$ possesses a smaller bandgap, it shows low absorption ability in the range of 2.0–3.0 eV with a small peak above the bandgap that originates from the isolated and extremely localized conduction band of this composition. Controlling the chemical composition to form a family of $\text{Cs}_{3+n}\text{M}^{2+}_n\text{Sb}_2\text{X}_{9+3n}$ layered MHDPs, their corresponding photovoltaic properties can be successfully tuned.

Regarding the great interest in optoelectronic material exploration on MHDPs, Lin et al. has introduced a new 3D perovskite-type structure beyond the double perovskite ($\text{A}_2\text{BB}'\text{X}_6$) as quadruple perovskite halides $\text{A}_4\Box\text{B}^{2+}\text{B}'_2\text{X}_{12}$ ($\Box$ = vacancy, A = Cs; B^{2+} = Zn, Cd; B' = Sb, Bi; X = Cl, Br and I) with a vacancy-ordered 3D crystal structure in $Fd\bar{3}m$ space group [167, 168]. In this structure, every two B^+ cation in $\text{A}_2\text{BB}'\text{X}_6$ double perovskite is replaced by a vacancy and a B^{2+} cation. Among the calculated materials, $\text{Cs}_4\text{CdSb}_2\text{Cl}_{12}$ and $\text{Cs}_4\text{CdBi}_2\text{Cl}_{12}$ showed enough thermodynamic stability to form at room temperature. These newly designed materials showed direct bandgaps of 2.93 and 3.05 eV with a 3D electronic structure. It is believed that these findings can provide a new perspective for optoelectronic material design and expanding the research on MHPDs.

A summary of all the highlighted information regarding the optoelectronic properties of MHDPs mentioned in this work can be found in Table 2.

6 Optoelectronic applications of MHDPs

It has been predicted that MHDPs have a large potential for different applications including solar cells, laser, lighting, bio-imaging and detectors. However, on the contrary to Pb-based halide perovskites, so far rare applications have been studied for this developing class of materials due to the poor knowledge of MHDPs. It is still in its infancy stage for the application of MHDPs. Only a limited number of MHDPs (e.g. $\text{Cs}_2\text{AgBiBr}_6$ and $\text{Cs}_2\text{AgInCl}_6$) have been implemented in diverse optoelectronic devices, such as solar cells, X-ray detectors, LEDs and photodetectors. Here, we summarize the state-of-the-art applications for the MHDPs considering their characteristic optoelectronic properties.

6.1 Solar cells

In the past few years, intensive efforts have been devoted to realize the photovoltaics of MHDPs and clarify some of their relevant characteristics namely optoelectronic

properties and thin-film morphology [48]. Ning et al. reported the first demonstration of the $\text{Cs}_2\text{AgBiBr}_6$ solar cells with the device configuration of the indium tin oxide (ITO)/Compact- TiO_2 (C- TiO_2)/ $\text{Cs}_2\text{AgBiBr}_6$ /2,2',7,7'-Tetrakis[N,N-di(4-methoxyphenyl)amino]-9,9'-spirobifluorene (Spiro-OMeTAD)/Au with a PCE of 1.11% [57]. Upon light excitation, they found coexistence of the free carriers and excitons inside the operation layer of $\text{Cs}_2\text{AgBiBr}_6$ with an impressively long diffusion length of around 110 nm.

Very recently, Igbari et al. [60] investigated the influence of vacuum sublimation and solution processing on the optoelectronic properties and the resulting photovoltaic performance of $\text{Cs}_2\text{AgBiBr}_6$ thin-films. That comparison confirmed the viability of the solution-based approach to producing $\text{Cs}_2\text{AgBiBr}_6$ thin-film with an inherently better crystallinity, moderately narrower bandgap, higher charge carriers mobility, and long carrier lifetime. These outcomes were attributed to the right composition stoichiometry of solution-processed $\text{Cs}_2\text{AgBiBr}_6$ thin-films that enabled corresponding solar cells to generate an encouraging PCE of 2.51%. A summary of all the thus far reports on MHDP solar cells can be seen in Table 3. In some works, the material stability was also carefully examined, which showed satisfactory stability of MHDP solar cells for long-time storage in ambient conditions.

Despite these strenuous efforts, the PCE of MHDPs is still far behind those of Pb-based counterpart solar cells. Considering the bandgap range observed for most of these materials, they can be rated as a talented candidates for tandem solar cells [169]. As mentioned before, to narrow the bandgap of $\text{Cs}_2\text{AgBiBr}_6$, Liu et al. [131] introduced Sb^{3+} into the structure of the material up to 75%, which caused shrinkage of 0.25 eV in the material's bandgap value. Further fabrication of the solar cells with the architecture of fluorine-doped tin oxide (FTO)/C- TiO_2 /Mesoporous- TiO_2 (M- TiO_2)/ $\text{Cs}_2\text{AgSb}_x\text{Bi}_{1-x}\text{Br}_6$ /Spiro-MeOTAD/Au, an improvement of the PCE from 0.19% ($x = 0$) to 0.25% ($x = 0.25$) was observed. It was presented that $\text{Cs}_2\text{AgBiBr}_6$ solar cell devices can properly work under the temperature range of 50–70 °C at operational conditions, and also considerably higher temperatures during the device fabrication process [48, 170]. So, in terms of thermal stability, $\text{Cs}_2\text{AgBiBr}_6$ material has superior tolerance related to traditional Pb-based perovskites. To improve the PCE, Yang et al. reported a feasible strategy, in which a thin interlayer of di-tetrabutylammonium cis-bis(isothiocyanato) bis(2,2'-bipyridyl-4,4'-dicarboxylato)ruthenium(II) (N719) dye is deposited between the absorbing-layer and hole-transporting layer (HTL). The roles of this thin interlayer were attributed to extending the absorption spectrum, accelerating the hole-transportation, reducing the charge carrier recombination, and adjusting the band alignment of

Figure 10: (a) General design principle for the layered halide double perovskites $\text{Cs}_{3+n}\text{M}^{2+}_n\text{Sb}_2\text{X}_{9+3n}$ ($\text{M} = \text{Sn}, \text{Ge}$) [166]. Copyright 2018, American Chemical Society. (b) Calculated band structures of $\text{Cs}_3\text{Sb}_2\text{I}_9$, $\text{Cs}_4\text{CuSb}_2\text{I}_{12}$, $\text{Cs}_4\text{SnSb}_2\text{I}_{12}$ and $\text{Cs}_4\text{GeSb}_2\text{I}_{12}$ from left to right [166]. Copyright 2018, American Chemical Society. (c) Calculated absorption spectra of $\text{Cs}_3\text{Sb}_2\text{I}_9$, $\text{Cs}_4\text{CuSb}_2\text{I}_{12}$, $\text{Cs}_4\text{SnSb}_2\text{I}_{12}$ and $\text{Cs}_4\text{GeSb}_2\text{I}_{12}$ [166]. Copyright 2018, American Chemical Society. (d) Photothermal deflection optical absorption spectroscopy (PDS) spectrum of neat $\text{Cs}_2\text{AgBiBr}_6$ thin-film. Inset: Tauc plot with the calculated indirect band-gap reported [179]. Copyright 2020, American Chemical Society. (e) EQE measured with illumination from the ITO (blue curve), from the gold (orange curve) and the modelled n -EQE (black dashed curve) [179]. Copyright © 2020, American Chemical Society. (f) Current generation at a distance x from the ETL (black curve) and a distance $435 - x$ from the HTL (red curve) in the case of n -side illumination [179]. Copyright © 2020, American Chemical Society. (h) Excitation (blue) and emission (red) scans for $\text{Cs}_2\text{Na}_{1-x}\text{Bi}_{1-x}\text{Mn}_{2x}\text{Cl}_6$ ($x = 0.004$) [172]. Copyright 2019, American Chemical Society. I - V curves in the dark for (i) pristine $\text{Cs}_2\text{AgBiBr}_6$ and (m) PEA- $\text{Cs}_2\text{AgBiBr}_6$ single-crystals [66]. 2019 WILEY-VCH Verlag GmbH & Co. KGaA, Weinheim. (n) Obtained sensitivity under different bias of the corresponding $\text{Cs}_2\text{AgBiBr}_6$ and PEA- $\text{Cs}_2\text{AgBiBr}_6$ X-ray detectors [66]. 2019 WILEY-VCH Verlag GmbH & Co. KGaA, Weinheim. Dark I - V of single-crystal $\text{Cs}_2\text{AgBiBr}_6$ photovoltaic device at (o) 300 K and (p) 77 K [207]. 2018 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (q) Temperature dependence of $\text{Cs}_2\text{AgBiBr}_6$ detector sensitivity to X-rays [207]. 2018 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (r) Optical photos of a 100 mm-thick $\text{Cs}_2\text{AgBiBr}_6$ /PVA (2:1 weight ratio) and SEM top images of the $\text{Cs}_2\text{AgBiBr}_6$ /PVA composite film [65]. Copyright 2015, Royal Society of Chemistry. (s) X-ray induced photocurrent responses of one detector at both flat and curved (10 and 2 mm bending radii) states [65]. Copyright 2015, Royal Society of Chemistry. (t) I - V curves of $\text{Cs}_2\text{AgBiBr}_6$ single-crystals based on Ag electrodes at different wavelengths at 100 K [64]. Copyright 2015, Royal Society of Chemistry.

Table 3: Summary of the photovoltaic parameters of the MHDP solar cells.

FF	J_{sc} (mA/cm ²)	V_{oc} (V)	PCE %	Device structure	Stability	Ref.
0.69	1.78	1.07	1.32	ITO/SnO ₂ /Cs ₂ AgBiBr ₆ /P3HT ¹ /Au	30 days in ambient with humidity 40–60%	[56]
0.69	1.51	1.07	1.11	ITO/C-TiO ₂ /Cs ₂ AgBiBr ₆ /SpiroOMeTAD/Au	Not reported	[57]
0.69	3.19	1.01	2.23	ITO/Cu-NiO/Cs ₂ AgBiBr ₆ /C60/BCP ² /Ag	30 days in ambient with humidity 50%	[59]
0.67	1.02	1.02	1.26	FTO/C-TiO ₂ /Cs ₂ AgBiBr ₆ /PTAA ³ /Au	Not reported	[61]
0.63	3.93	0.98	2.43	FTO/C-TiO ₂ /M-TiO ₂ /Cs ₂ AgBiBr ₆ /Spiro-OMeTAD/Au	25 days in ambient	[58]
0.65	3.82	1.01	2.51	ITO/C-TiO ₂ /Cs ₂ AgBiBr ₆ /Spiro-OMeTAD/MoO ₃ ⁴ /Ag	15 days in ambient	[60]
0.68	1.1	1.1	1.37	FTO/C-TiO ₂ /Cs ₂ AgBiBr ₆ /P3HT/Au	250 h in ambient	[235]
0.69	2.58	1.07	1.91	FTO/C-TiO ₂ /Cs ₂ AgBiBr ₆ /P3HT/Cu	68 days in humidity of 68 ± 7%	[62]
0.52	5.13	1.06	2.84	FTO/C-TiO ₂ /M-TiO ₂ /Cs ₂ AgBiBr ₆ /N719/Spiro-OMeTAD/Ag	16 days in humidity of 30–40%	[171]
73.6	3.83	0.99	2.79	ITO/SnO ₂ /Cs ₂ AgBiBr ₆ /zinc chlorophyll derivative (Zn-Chl)/Ag	50 days in ambient	[236]
0.70	1.33	1.10	1.03	FTO/TiO ₂ /Cs ₂ AgBiBr ₆ /Spiro-OMe-TAD/Ag	Not reported	[179]

the active layer for the carrier collecting layers. That enabled a PCE of 2.84% with a simultaneous improvement in the stability of Cs₂AgBiBr₆ solar cells [171].

The problem with the potential MHDPs predicated by theoretical calculations as promising light absorber is mainly related to their big enthalpy formation, dissolubility of their precursors, poor thin-film quality [72, 165, 172]. In addition to these challenges, insufficient knowledge of the fundamental photophysics of MHDP thin-films has resulted in their low-performance in solar cells [173].

While most of the previous studies mainly focused on the photovoltaic performance of Cs₂AgBiBr₆ MHDP, comprehensive knowledge of its long-term stability and degradation mechanism is still scarce. Recently, we demonstrated the development of high-quality Cs₂AgBiBr₆ thin-film with a grain size in the range of 300–500 nm via a feasible solution method [62]. Implementing planar thin-film solar cell could achieve a decent efficiency of 1.91%. The stability of these Cs₂AgBiBr₆ photovoltaic devices was studied over long storage of 68 days in ambient conditions that helped to understand a dual-ion-migration phenomenon in Cs₂AgBiBr₆ double perovskite. Theoretical calculations consistently confirmed the low formation energy for Ag and Br vacancies, and small diffusive energy barriers that facilitated ion-migration effect. Given these, a mechanism of vacancy-mediated ion-migration was proposed to be responsible for this phenomenon. These key findings

are of vital importance for MHDPs to outstretch their optoelectronic applications where mixed electronic, ionic and photonic properties are desired.

In general, the performance of the solar cells based on MHDPs is still far behind their Pb-based counterparts, suggesting some serious limitations that need to be carefully addressed. In the search for alternative Pb-free perovskites, the absorber should have near-ideal optoelectronic properties (e.g. *Direct* bandgap preferably between 1 and 1.8 eV, long electron and hole diffusion length and low defect trap density) [126]. The best-reported PCE for MHDPs is 2.84% at a bandgap of around 2.25, with an open-circuit voltage (V_{oc}) of 1.06 V, short-circuit current (J_{sc}) of 5.13 mA/cm² and fill factor (FF) of 0.52 [171]. Historically, a large voltage-deficit was obtained in photovoltaic technology, which however has been gradually improved due to technical progress in material processing and surface passivation [174]. On the other hand, the severely inhibited J_{sc} should be a major obstacle to high-performance solar cell devices [175]. To have an optimum absorption due to *indirect* bandgap of investigated MHDPs for solar cells, namely Cs₂AgBiBr₆, high thicknesses on the order of tens to hundreds of micrometres is necessary. This highlights the importance of long charge-carrier diffusion length in the absorbing layer to generate high short-circuit currents. To date, several different values have been reported for charge-carrier mobility and diffusion length of MHDPs mainly in the form of thin-film and single-crystal [64, 173, 176–178]. Very recently, Longo et al. reported an evaluation of the carrier diffusion length of vapour-deposited Cs₂AgBiBr₆-based solar cells with the best PCE of 1.03%, J_{sc} of 1.33 mA/cm², V_{oc} of 1.10 eV and FF of 0.70 [179]. With the Shockley–Queisser assumptions at a

¹ Poly(3-hexylthiophene).

² Bathocuproine.

³ Poly[bis(4-phenyl)(2,4,6-trimethylphenyl)amine].

⁴ Molybdenum trioxide.

bandgap of 2.25 eV, the thermodynamic limit should be J_{sc} of 9.79 mA/cm², V_{oc} of 1.93 eV and PCE of 17.6%. Every 60 mV loss in V_{oc} from this limit corresponds to a reduction of an order-of-magnitude in the device's external radiative efficiency (ERE) [180–183]. Therefore, for a device with V_{oc} of 1.10 eV, the loss was ~800 mV, which declared a sufficiently low ERE of $\sim 10^{-13}$ for a Cs₂AgBiBr₆ solar cell device. As a comparison, this value is around 0.1 for the best organic-inorganic Pb-based perovskite solar cells. This indicated an intensely high rate of non-radiative recombination in Cs₂AgBiBr₆ device, which should originate from substantially large trap densities in the absorber and interfaces. Longo et al. discussed that a shallow absorption edge with an Urbach energy of 70 meV (Figure 10d) [179] was a strong indicator of a large density of sub-bandgap states in Cs₂AgBiBr₆ thin-film. These states could severely facilitate fast charge-carrier trapping and the ulterior non-radiative recombination process [184]. This scenario was more problematic for wide bandgap light absorbers because the positions of VBM and CBM were far from the optimum energetic match that has been so far investigated for the promising charge extraction layers [183]. By an accurate examination of the external quantum efficiency (EQE) spectra of semi-transparent Cs₂AgBiBr₆ solar cells, they found an ineffective collection of electrons by the extraction layer when they had to pass through the entire active layer (Figure 10e). They also found that the strongly absorbed wavelengths could not reach the electron-transporting layer (ETL) (Figure 10e). These observations signified the short electron diffusion as the limiting factor for low short-circuit current of Cs₂AgBiBr₆ solar cells. It was shown that Cs₂AgBiBr₆ double perovskite possesses a short electron diffusion length of 30 nm and a longer hole diffusion length of greater than 150 nm ascribed to a high density of electron traps in Cs₂AgBiBr₆ thin-film (Figure 10f) [179].

In general, the major challenges for high-efficiency MHPs solar cells should be attributed to their short electron diffusion length, high defect trapping/low-quality light-absorbing and unsuitable ETL/HTL matches. Exhibiting these optoelectronic properties, another potential choice can be semi-transparent perovskite solar cells with a promising perspective for diverse applications of tandem devices, building-integrated photovoltaics and vehicle-integrated photovoltaics [185].

6.2 Light-emitting diodes

For lighting applications, white emission from a single emitter layer is of particular interest because significant advantages such as simple device structure, low self-

absorption and good colour stability are commonly observed in mixed and multiple emitters [186]. Although hybrid Pb-based perovskites with low-dimensional structures have attained tremendous attention as broadband-emission materials, they barely deliver high PL quantum yield [187]. Broadband and white emission normally are ascribed to the self-trapped excitons (STEs) that are typically observed in semiconductors with localized carriers and a soft lattice [188, 189]. In 2018, Tang et al. demonstrated the stable and efficient white-light emission of doped (0.04% Bi³⁺) Cs₂(Ag_{0.60}Na_{0.40})InCl₆ double perovskite with a broad spectrum (400–800 nm) that occurred through self-trapped excitons [190]. The origin of this ability was attributed to the Jahn–Teller distortion in (AgCl₆)⁵⁻ octahedron upon illumination in the excited state. As discussed before, Cs₂AgInCl₆ suffers from parity-forbidden transition. However, Na⁺ incorporation into the lattice was found to be beneficial to adjust the wave function's parity of the self-trapped excitons. This yielded an ultimate reduction into its electronic dimensionality [165]. Accordingly, an enhancement in PL efficiency (warm-white light efficiency of 86 ± 5% and high stability of ~1000 h) was observed, which was three orders of magnitude of the one for pure Cs₂AgInCl₆ perovskite. It was proposed that this substantial stability originates from the nearly defect-free lattice of the material and strongly bound excitons that all together sufficiently inhibit PL quenching. This outstanding photometric performance emphasized the promise for white-phosphor applications. Regarding this point, MHPs also have displayed promising potential for phosphor-converted light-emitting diode (pc-LED) applications. In general, pc-LEDs are enabled to generate white light with a remarkable performance of almost double of the fluorescent lights and ten times of the incandescent lights [172]. Majher et al. [172] reported Mn²⁺-doped cubic double perovskite Cs₂NaBiCl₆, in which a strong absorption near-UV light was observed (Figure 10g). This was attributed to the localized excitations that are centred on Bi³⁺ sites in the parent lattice. Insertion of the strongly electropositive Na⁺ cations into the octahedra of the lattice yielded a zero-dimensional electronic structure [191, 192]. Normally, localized electronic states are favourable for the formation of self-trapped and dopant-bound excitons [192]. Undoped host compound, Cs₂NaBiCl₆, showed a considerably weak PL, while intense orange-red photoluminescence was realized through Mn²⁺ doping. This trend was associated with the energy transfer from Bi³⁺ to Mn²⁺ [172]. As discussed before, Cs₂AgInCl₆ was a wide bandgap semiconductor with a 3D electronic structure. Through illumination, Mn²⁺-doped Cs₂AgInCl₆ absorbed photons and generated electron-hole pairs. These photo-generated carriers were presumed to migrate through the

lattice until they were trapped and recombined at the Mn^{2+} sites. In contrast, for the case of Mn^{2+} -doped $\text{Cs}_2\text{NaBiCl}_6$, the light absorption occurred through localized excitations of $[\text{BiCl}_6]^{3-}$ octahedral. Then their energy was transferred to the neighbouring Mn^{2+} sites that were assumed as the activators. The observed red-emission in Mn^{2+} -doped $\text{Cs}_2\text{AgNaCl}_6$ spectrum particularly should be advantageous for some applications of tri-colour pc-LEDs employing red and green phosphors. However, fairly low quantum yield (3–5%) and lack of absorbance at higher wavelengths than 350 nm were problematic. Besides, as an efficient phosphor for white lighting applications, a red-shift in the excitation wavelength would be beneficial because it provided a stronger overlap with the emission spectrum of $\text{Ga}_{1-x}\text{In}_x\text{N}$ LED sources. Tuning the bandgap of the material adopting other possible cations or halide anions should be a route to reach this goal. These findings encourage further investigation of white-light MTHDs emitters towards the next generation of lighting technologies.

6.3 Photodetectors

X-ray detection is of great interest in a variety of applications including medical diagnostics, non-destructive product inspection and versatile scientific research [193, 194]. A higher spatial resolution can achieve in direct route with simpler system configuration to convert X-ray radiation into an electrical signal, while in indirect methods, X-ray first is converted into the photons by scintillating phosphors following with detection by photodiodes [195]. Recently, solution-grown halide perovskites have exhibited exceptional properties of high X-ray attenuation coefficient, long carrier drift length per unit electric field (defined as $\mu\tau$ product, where μ is the carrier mobility and τ is the carrier lifetime), and facile integration with silicon-based electronics for imaging intentions [196]. So far X-ray detectors based on Pb-halide perovskites have demonstrated an outstanding sensitivity of $2.1 \times 10^4 \mu\text{CGy}_{\text{air}}^{-1} \text{cm}^{-2}$ [197, 198]. Despite this exceptional success, Pb toxicity is a barrier due to its fatal impacts on the human body [199]. Moreover, it is highly motivated for further optimization of the best-reported detection limit of Pb-based halide perovskites, because a reduction in the radiation dose during medical tests can strikingly diminish the cancer risk [200]. A small detection limit is also necessary for X-ray security screening systems [201]. Lowering this detection limit can enhance the spatial resolution of the images [202]. For these reasons, developing Pb-free single-crystals with a low detection limit for X-ray detection applications is of great importance [203].

Although the *indirect* characteristics of the $\text{Cs}_2\text{AgBiBr}_6$ bandgap (2.1 eV) relatively diminishes its potential for photovoltaics and lighting applications, it carries some promising features that enable its capability for X-ray detection applications as described here. (i) For an X-ray detector, the absorption coefficient (α) is a function of $\alpha \propto Z^4/E^3$ (Z = atomic number and E = radiation energy), while in photovoltaics and LEDs, it is determined by the material's optical-transition type and bandgap value [204]. For the case of $\text{Cs}_2\text{AgBiBr}_6$, it preferably has the heaviest stable element (Bi) in its structure with an average Z value of 53.1, higher than the Z value of 48.9, 45.1 and 34.0 for MAPbI_3 , MAPbBr_3 and α -Se, respectively. This implies more efficient X-ray attenuation and improved signal current. (ii) The $\mu\tau$ product indicates the carrier transportation per unit electric field before annihilation that pushes the charge extraction efficiency. The *indirect* characteristic of $\text{Cs}_2\text{AgBiBr}_6$ bandgap causes a long PL lifetime, which is remarkably higher than the reported magnitude for MAPbBr_3 single-crystals (357 ns), therefore a decent $\mu\tau$ product is predicted for $\text{Cs}_2\text{AgBiBr}_6$ [48, 196, 205]. (iii) In an efficient X-ray detector, high resistivity is the key to mitigating dark current and consequently the noise current. This value is found to be 10^9 – $10^{11} \Omega \text{cm}$ for $\text{Cs}_2\text{AgBiBr}_6$, higher than those for MAPbX_3 ($X = \text{Cl}, \text{Br}, \text{I}$; 10^7 – $10^8 \Omega \text{cm}$). (iv) In halide perovskites, severe halide migration widely plagues their detection limit [206]. In contrast, $\text{Cs}_2\text{AgBiBr}_6$ single-crystals have lower field-driven ionic migration that makes the material withstand a large external bias to improve the signal current and suppress a superlinear growth in the noise current. On the count of these features, fabricating X-ray detectors based on non-toxic stable $\text{Cs}_2\text{AgBiBr}_6$ single-crystals is highly promising. To this end, Tang et al. [196] successfully examined the application of $\text{Cs}_2\text{AgBiBr}_6$ single-crystals to fabricate X-ray detectors with high sensitivity and low detection limits. They presented an enhancement in the material's carrier transport by increasing the mobility from 3.17 to $11.81 \text{ cm}^2 \text{V}^{-1} \text{s}^{-1}$ and a reduction in the surface trap densities from 4.54×10^9 to $1.74 \times 10^9 \text{ cm}^{-3}$ through thermal annealing and surface treatment. This came from a relief in the $\text{Ag}^+/\text{Bi}^{3+}$ disordering arrangement that adequately improved $\text{Cs}_2\text{AgBiBr}_6$ single-crystals' resistivity. As expected, $\text{Cs}_2\text{AgBiBr}_6$ single-crystals showed a suppressed field-driven ionic migration that permitted applying a large external bias to reduce the dark current. A promising sensitivity of $105 \mu\text{CGy}_{\text{air}}^{-1} \text{cm}^{-2}$ and a low detection limit of $59.7 \text{ nGy}_{\text{air}}^{-1} \text{s}^{-1}$ were found for the optimized $\text{Cs}_2\text{AgBiBr}_6$ X-ray detector systems. All these characteristics benefit for X-ray security screening systems and the applications of medical diagnostics. Nevertheless, the disordered arrangement of $[\text{AgBr}_6]^{5-}/[\text{BiBr}_6]^{3-}$ in the most explored case,

$\text{Cs}_2\text{AgBiBr}_6$, usually causes some unexpected structural distortion that extensively influences the photoelectric properties. Yuan et al. [66] innovatively showed the ability of phenylethylamine bromide to in situ regulation of $\text{Cs}_2\text{AgBiBr}_6$ order-disorder phase transition. In a combination of theoretical and experimental studies, they proved that modifying $[\text{AgX}_6]^{5-}$ and $[\text{BiX}_6]^{3-}$ octahedra ordering decreased the defect density in the structure and also suppressed the self-trapped exciton formation (Figure 10h and i). In accordance, this enhanced the material's charge carrier mobility. The as-fabricated X-ray detectors based on PEA- $\text{Cs}_2\text{AgBiBr}_6$ single-crystals illustrated extraordinarily high sensitivity of $288.8 \mu\text{CGy}_{\text{air}}^{-1} \text{cm}^{-2}$ that is largely superior to those of their counterparts with less structural ordering (Figure 10j). In another work, Roeffaers et al. investigated the intrinsic photophysical pathways in $\text{Cs}_2\text{AgBiBr}_6$ single-crystals at room and liquid-nitrogen temperatures. They showed deficient charge carrier dynamic for $\text{Cs}_2\text{AgBiBr}_6$ single-crystal X-ray detectors at room temperature [207]. A substantial enhancement of carrier lifetimes of $\text{Cs}_2\text{AgBiBr}_6$ single-crystals was notified from 700 ns at room temperature to over 1500 ns at liquid-nitrogen temperature. This caused a huge boost in devices' sensitivity from $316 \mu\text{CGy}^{-1} \text{cm}^{-2}$ at room temperature to $988 \mu\text{CGy}^{-1} \text{cm}^{-2}$ at liquid-nitrogen temperature (Figure 10k–m).

Flexible X-ray detectors are of significant interest due to their feasible adhesion to uneven surfaces, lightweight, transferable X-ray diagnostic instruments and potential capability in correcting image distortion in the cone-beam quantified tomography [208]. However, a tens-of-micrometre thickness is required for halide perovskite devices to effectively absorb X-rays [209]. This will limit their flexibility due to crack formation and film delamination from the substrate. To overcome this, Li et al. [65] developed a new strategy by embedding composite films of $\text{Cs}_2\text{AgBiBr}_6$ in a polymer matrix. Polymers containing hydroxyl functional groups intensively modified $\text{Cs}_2\text{AgBiBr}_6$ dispersion in the composite that could deliver large-area dense films (Figure 10n). Fabricating X-ray detectors based on this composite film committed a promising sensitivity of $40 \mu\text{CGy}_{\text{air}}^{-1} \text{cm}^{-2}$. Flexing and bending the relevant detectors at a 2 mm radius (equivalent to a maximum 5% tensile/compressive strain in the composite films), no degradation could be detected in the device's performance (Figure 10).

Single-crystals are considered as an ideal test platform to investigate the characteristics of double perovskites due to the absence of the grain boundaries and low densities of traps. Dang et al. surveyed the photodetectors based on centimetre-sized $\text{Cs}_2\text{AgBiBr}_6$ single-crystals, in which different metals of Au, Ag and Al were applied as the contact

electrode. An excellent photoresponse behaviour was found for Ag-based devices (Figure 10p) [64], which was attributed to the better ohmic contact between $\text{Cs}_2\text{AgBiBr}_6$ single-crystals and Ag electrodes. Furthermore, a clear phase transition in $\text{Cs}_2\text{AgBiBr}_6$ single-crystals was notified that strongly affected the function of the corresponding devices. Carrying out the measurements at different applied voltages and wavelengths in a vacuum atmosphere at a low temperature of 100 K, no ohmic-contact behaviour could be seen for $\text{Cs}_2\text{AgBiBr}_6$ single-crystals. This poor behaviour possibly originated from the variations in the crystal structure ordering induced by the material's phase transition [210]. Therefore, it is important to consider the consequence of this phase transition on the device performance and find the right approaches to manage it.

6.4 Photocatalysts

CO_2 is considered as the main greenhouse gas causing global warming. However, it can also be advantageous to produce value-added chemicals and solar fuels (e.g. CO, HCOOH, CH_3OH , CH_4) by its reduction through photocatalytic strategies under light illumination. Recently, semiconductor quantum dots (QDs) have been classified as one of the promising candidates for initiating highly efficient artificial photosystems. This ongoing attention comes from some of the attracting characteristics of semiconductor QDs, including multiple exciton generation, abundant surface sites, excellent light-harvesting, feasible charge-carrier regulation and facile synthesis. Although Pb-based halide perovskite QDs have indicated supreme optoelectronic abilities, the presence of toxic Pb and also limited intrinsic stability of this class of the materials to moisture hamper their widespread practical applications [211]. Very recently, Zhou et al. [212] for the first time reported the synthesis of pure cubic shape $\text{Cs}_2\text{AgBiBr}_6$ QDs, with a reasonably high optical absorption coefficient, through a simple hot-injection method (Figure 11a). It was shown that the high-crystalline $\text{Cs}_2\text{AgBiBr}_6$ QDs could preserve their structural stability in low polarity solutions for about three weeks. $\text{Cs}_2\text{AgBiBr}_6$ QDs also showed strong phase uniformity at different conditions of atmospheric humidity and light soaking time (Figure 11b), which all validate the material's striking stability against moisture, temperature and light, as crucial factors for the vast optoelectronic or photochemical applications. $\text{Cs}_2\text{AgBiBr}_6$ QDs-based photosystem exhibited high stability and selectivity to produce both CO and CH_4 (Figure 11c). It is known that the ligands of QDs can affect the exchange of surface substances and excitons' transfer into the system, where

the organic ligand blocks the efficient photogenerated charges transportation from photocatalysts to reactants. This promotes accumulation of the photoconversion products that intermediates in the ligand shell. This phenomenon yields catalyst poisoning diminishes activity, and finally dampens the photocatalytic performances [213]. On the other hand, low ligand density on QDs can enhance the photoconversion performance due to the effective carrier transport in the system. Considering these synthetic notes and optimization of the operation condition, CO and CH₄ production rates of 14.1 and 9.6 $\mu\text{mol g}^{-1}$ were found for the Cs₂AgBiBr₆ QDs photosystem. It was proposed that the proper position of the Cs₂AgBiBr₆ CBM derived the CO₂ reduction (Figure 11d). This observation triggered the great potential of non-toxic stable MHPDs for photocatalysts.

In another study by Zhang et al., an alcohol-based photocatalytic system was successfully implemented, in which Cs₂AgBiBr₆ was used as the light harvester to degrade different dyes [67]. Inspiringly, Cs₂AgBiBr₆ showed remarkable chemical stability in the presence of the ethanol during the whole photocatalytic processes. Likewise, ethanol solvent did not undergo any photocatalytic oxidation. Investigating the degradation process of four different dyes, a pseudo-zeroth-order reaction kinetics was revealed for Cs₂AgBiBr₆ (Figure 11e) that was in opposition to the pseudo-first-order reaction kinetics identified for CdS systems. In the studied systems in this work, dye molecules experienced a thorough mineralization process and the main active species were confirmed to be superoxide radical (O₂^{•−}) (Figure 11f). Additionally, it was shown that Pt and Au deposition facilitates the transformation of photogenerated electrons from Cs₂AgBiBr₆ to the metal electrodes. This design caused an impressive increase in the photocatalytic degradation rate, around two times, which surpassed CdS systems under the same reaction conditions. PL decay of the Cs₂AgBiBr₆ presented a fast initial drop due to multiple recombination centres in the Cs₂AgBiBr₆ powder followed by a slow decay that delivered an average lifetime of 3.18 ns. While Pt and Au deposition substantially decreased this average lifetime to 0.71 and 1.52 ns, respectively (Figure 11g). This indicated the appearance of non-radiative centres, as well as interfacial charge transportation that all together demonstrate a promotion in the carrier separation after Pt or Au deposition. Applying five runs of the photocatalytic reaction confirmed the promising stability of the Cs₂AgBiBr₆ with no obvious decline in the photodegradation efficiency (Figure 11h). These results stimulate further efforts to expand the family of MHPDs for a broad range of possible applications in photocatalysis.

6.5 Sensors

One of the unique characteristics of Cs₂AgBiBr₆ is its remarkably high stability in the ambient environment [48, 214]. Due to the great dependency of the Cs₂AgBiBr₆ electrical properties on the humidity, Weng et al. [63] devoted some effort to excavate its potential as a humidity sensor. The proposed structure for the Cs₂AgBiBr₆ thin-film humidity sensor can be seen in Figure 11i. For different applications namely weather forecast, medical tools and agriculture, humidity measurement is a pivotal demand [215]. For a well-performed humidity sensor, the commonly required features include high sensitivity, preferential linearity, the short response time (t_{res}) and recovery time (t_{rec}), good stability and reliability [216]. The humidity sensors based on stable Cs₂AgBiBr₆ thin-films showed a superfast response time of 1.78 s and a recovery time of 0.45 s in the operational condition with different relative humidity (RH) of 5–75% (Figure 11j) [63]. From this point of view, the performance of the Cs₂AgBiBr₆ thin-film humidity sensors was superior to that of other perovskite-based humidity sensors [217]. This outstanding sensing behaviour was presumed to be due to the plane structure of the Cs₂AgBiBr₆ thin-film that facilitated the volatilization of the water molecules during the desorption process. It is in contrary to the porous structure in ceramic humidity sensors, that traps the condensed water molecules in the pores, decelerates the volatilization process and finally causes much longer recovery times than the response times [218, 219]. Another possible reason for this high-performance sensing ability was related to the weaker bond between the surface of the Cs₂AgBiBr₆ thin-film and water molecules than the one in metal-oxide-ceramic humidity sensors, because the hydrogen bond H-Br is weaker than H-O bond. Therefore, the first-layer water molecules can feasibly volatilize from the Cs₂AgBiBr₆ surface. Moreover, the Cs₂AgBiBr₆ thin-film humidity sensors demonstrated an excellent sensitivity of 1162 in the RH range of 15–78% (25 °C) (Figure 11k). In terms of long-term stability, the Cs₂AgBiBr₆ thin-film humidity sensors exhibit unchanged resistance after repeated measurement for 13 days under different RH values (Figure 11l). These observations validated the considerable tolerance and applicability of the Cs₂AgBiBr₆ thin-film humidity sensors for a daily life humidity measurement. Previous studies on the Pb-based halide perovskites' electronic humidity sensors mainly focus on MAPbI_{3-x}Cl_x perovskites. However, the moisture and thermal stability of this Pb-halide perovskite poses serious concerns on their long-term operation [220, 221]. Therefore, considering excellent stability and superfast response and recovery speed, it is believed that

Figure 11: (a) TEM image of $\text{Cs}_2\text{AgBiBr}_6$ QDs [212]. (b) XRD patterns of absolute ethanol washed $\text{Cs}_2\text{AgBiBr}_6$ QDs stored in different environments [212]. (c) Comparison of photocatalytic CO_2 reduction performance of the as-prepared $\text{Cs}_2\text{AgBiBr}_6$ QDs and washed QDs [212]. (d) Schematic diagram of the photoreduction of CO_2 on the surface of $\text{Cs}_2\text{AgBiBr}_6$ QDs [212]. (e) Kinetic curves of different dyes degradation [67]. 2019 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (f) The DMPO spin-trapping ESR spectra of $\text{Cs}_2\text{AgBiBr}_6$ for $\cdot\text{O}_2$ under different visible-light irradiation time [67]. 2019 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (g) TRPL of $\text{Cs}_2\text{AgBiBr}_6$, $\text{Cs}_2\text{AgBiBr}_6\text{-Pt}$ and $\text{Cs}_2\text{AgBiBr}_6\text{-Au}$ [67]. 2019 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (h) Photocurrent response of $\text{Cs}_2\text{AgBiBr}_6$, $\text{Cs}_2\text{AgBiBr}_6\text{-Pt}$ and $\text{Cs}_2\text{AgBiBr}_6\text{-Au}$ [67]. 2019 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (i) The schematic device structure of the $\text{Cs}_2\text{AgBiBr}_6$ thin-film humidity sensor [63]. 2019 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (j) The dynamic response and recovery characterization of $\text{Cs}_2\text{AgBiBr}_6$ thin-film humidity sensors [63]. 2019 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim. (k) I – V curves of humidity sensor at different humidity. Inset: the current versus RH. (l) The long-term stability of the sensor (aged under the exposure of the ambient ($\approx 22^\circ\text{C}$, $\approx 60\%$ RH)) toward different RH values [63]. 2019 Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim.

$\text{Cs}_2\text{AgBiBr}_6$ double perovskites might be a good candidate for a high-performance real-time humidity sensing.

6.6 Lasers

The development of high-efficiency semiconductor laser diodes has raised great attention to the examination of new compounds with the ability to emit in the visible and near-infrared range [222]. Some of the outstanding physico-chemical attributes of Pb-based perovskites (e.g. long-ranged ambipolar charge transport, low carrier effective mass, long carrier lifetimes and high photoluminescence quantum yields, accomplished by their feasible solution-process methods to fabricate large-scale product) highlight their great potential for laser materials [223–225]. Compared to the crystalline materials (e.g. ZnSe and organic semiconductors) that require grown at high operational temperatures, there are two distinct characteristics exclusive to perovskites that emphasize their promising

function for laser applications: (i) Perovskites possess amplified spontaneous emission (ASE) that is one order of magnitude lower than that of organic materials [226]. In general, ASE is optically amplified light from the spontaneous emission and also is assumed as superluminescence [227]. (ii) Controlling perovskites composition and surface morphology, the emission colour of the compound can be easily tuned over a broad range of wavelengths from 350 to 800 nm. Perovskite nanostructures, such as nanoplatelets and quantum dots, are much suitable for controlled lasing due to the observed optical cavities [228]. The capability of double perovskites for laser applications has been rarely researched so far. However, the abovementioned criteria shine the light on their functionality for this target application. Inspiringly in 1999, Fonseca et al. studied the doped- Cr^{3+} $\text{Cs}_2\text{NaGaF}_6$ single-crystals [229] because transition-metal ions are considered as optically active ions due to their electronic transitions. They observed an intense luminescence for transition-metal ions-based laser diodes [230]. Similarly,

MHDPs are supposed to be applicable in the laser applications with desired properties [231–234].

7 Conclusions and outlook

To accommodate a stable and non-toxic metal cation (e.g. Bi^{3+} , Sb^{3+}) in the perovskite structure with a 3D framework, one approach is to insert a monovalent metal cation into the lattice to form a double perovskite configuration with the generic formula of $\text{A}_2\text{BB}'\text{X}_6$, named elpasolite. This rich family involves more than 350 members, majority of them has 3D crystal structure. Versatile composition of these compounds offers a straightforward manipulation on their optoelectronic properties (e.g. bandgap and carrier transport, carrier effective mass and mobility). Moreover, the nanostructures of MHDPs, such as one-dimensional nanowire and 2D layered structures, provide the further method to control their optoelectronic properties for different applications. Initially motivated by providing an alternative light-absorber for Pb-halide perovskites with high stability and low toxicity, to date significant progress has been made in Pb-free double perovskites, from synthesis, fundamental understanding to the device fabrication and applications. The theoretical investigations have predicted that Pb-free double perovskites could deliver intriguing optoelectronic properties, for example, transition from indirect to direct bandgap, and absorption bandgap tuning from UV to near infrared. Together with superior stability against heat and moisture as well as intrinsically environmentally friendly, MHDPs therefore are highly prospective for broad range of applications. However, comprehensive knowledge of their microstructure and their potential applications is still largely elusive. Therefore, to make sustainable progress, there remain plenty of underlying challenges. Here, we envisage some potential directions for further exploration of this family of materials: (i) One of the most crucial obstacles that MHDPs encounter is the wide-bandgap property that hampers the absorption of a great portion of the solar spectrum. The *indirect* characteristic of the bandgap is another barrier, in turn, it causes a relatively infeasible charge carrier generation. The material bandgap is predicted to originate from its particular electron configuration and the consequent orbital interaction of the contributed elements into the structure. One way to change this intrinsic property is to incorporate different and still yet to be explored types of metal cations to alter the authorized electron configuration. To attain this, similar to Pb-based perovskites with the typical formula of ABX_3 , the structural stability of MHDPs is described by the proper tolerance factor and octahedral factor. Regulating these two factors

utilizing composition engineering, the incorporation of various metal cations of Mn^{2+} , Co^{2+} , Cu^{2+} , Ni^{2+} and Fe^{3+} can be assessed, which enables us to find structurally stable new members of this family with appropriate bandgap values. (ii) The localized defect states in the lattice and bulk of the double perovskites can detrimentally quench their function. Detailed studies on the charge carrier dynamic provide thoughtful concepts on understanding the mechanism of defect traps into the structure. More understanding on this part is assumed to be a definite way to discover the functional pathways towards long-lasting high-performance devices. (iii) Numerous works have discussed the critical role of light illumination in the defect curing and structural modification of Pb-based perovskites, while in the case of MHDPs, it has received poor attention. Hence, investigating the influence of light illumination on the materials' function either in the form of pure thin-film or in device structure is of great interest to deeply explore their photophysical and electronic characteristics. To this aim, the optical techniques, such as steady-state PL, micro-PL, TRPL, and transient absorption spectroscopy, can be powerful tools to understand the charge carrier and mobile ion dynamics in double perovskites. These spectroscopic techniques have been well developed to cover full timescales from femtoseconds to hours, to explore full ranges of carrier dynamic processes. Similar to halide perovskites, the dynamic recombination processes occurring in nanoseconds to microseconds have the most important interest because they are intimately correlated to the performance of the devices. Typically, the recombination processes include defect and surface trapping, exciton or free electron–hole recombination, Auger recombination, carrier diffusion and transfer/extraction in the devices, etc. Moreover, combined with confocal microscopy and other microscopic techniques, the advanced micro-spectroscopic techniques provide superior capability with spatial and temporal resolution and therefore making comprehensive physical understanding assessable into the materials, interfaces and devices.

To date, various optoelectronic applications, including solar cells, LEDs and detectors have been primarily demonstrated for MHDPs. However, for photovoltaics the reported performances are still not comparable to that of Pb-based perovskites. It is supposed that at this stage this class of perovskites cannot satisfactorily fulfil the requisitions of an ideal operation layer for photovoltaics due to their inferior photovoltaic properties (e.g. large and indirect bandgap, low absorption in the visible range, limited electronic dimensionality and formation of deep cation-on-cation antisite defects.). Nevertheless, the recent investigations have demonstrated the possibility to extend significantly the bandgap to an ideal energy of 1.5 eV that secures a Shockley-

Queisser limit of 32% for single junction solar cell. Taking into account the large flexibility to tune the optoelectronic properties by changing their composites, crystalline and nanostructures, we can see there is a large space to improve the performance of photovoltaic devices. However, compared to the great success of halide perovskites in solar cells, one has to accept the fact that MHDPS may not be a competitive candidate for photovoltaics. Being highly luminescent materials due to the PL mechanism of self-trapped exciton, MHDPS have been demonstrated successfully in high performance LED and laser. The intrinsic broad band spectrum fully covered the visible and high luminescence quantum yield, MHDPS can be potentially used for tuneable laser source and white light display, together with their advantages of high stability and environment friendly nature. In addition, the properties of their nanostructures have not yet been deeply explored and understood. With quantum confinement the nanocrystals of MHDPS are expected to have large possibility to change and improve the optoelectronic properties. One prospective is the applications in bioimaging but not yet well demonstrated. The nanocrystals or quantum dots of MHDPS can be an excellent candidate because of high luminescence, and tuneable spectrum covering the visible and near infrared. Importantly, there are non-toxic and can be water soluble. It is believed that pushing pass the current developing stage by fundamental understanding of their photophysical properties and structural variation will certainly open new avenue towards their implementation.

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